20A Digital MicroDLynx™: Non-Isolated DC-DC Power Modules

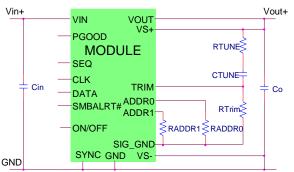
3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current



RoHS Compliant

Applications

- Distributed power architectures
- Intermediate bus voltage applications
- Telecommunications equipment
- Servers and storage applications
- Networking equipment
- Industrial equipment



Features

- Compliant to RoHS II EU "Directive 2011/65/EU"
- Compliant to RoHS EU Directive 2011/65/EU under exemption 7b (Lead solder exemption). Exemption 7b will expire after June 1, 2016 at which time this produc twill no longer be RoHS compliant (non-Z versions)
- Use ABB specified module version and process for SMT placement on bottom side of board (-D version only)
- Compatible in a Pb-free or SnPb reflow environment (Z versions)
- Compliant to IPC-9592 (September 2008), Category 2, Class II
- DOSA based
- Wide Input voltage range (3Vdc-14.4Vdc)
- Output voltage programmable from 0.45Vdc to 5.5Vdc via external resistor and PMBus^{TM #}
- Digital interface through the PMBus™ # protocol
- Tunable Loop™ to optimize dynamic output voltage response
- Flexible output voltage sequencing EZ-SEQUENCE
- Power Good signal
- Fixed switching frequency with capability of external synchronization
- Output over current protection (non-latching)
- Over temperature protection
- Remote On/Off
- Ability to sink and source current
- Cost efficient open frame design
- Small size: 20.32 mm x 11.43 mm x 8.5 mm (0.8 in x 0.45 in x 0.334 in)
- Wide operating temperature range [-40°C to 105°C (Ruggedized: -D), 85°C(Regular)]
- UL* 60950-1 2nd Ed. Recognized, CSA[†] C22.2 No. 60950-1-07 Certified, and VDE[‡] (EN60950-1 2nd Ed.) Licensed
- ISO** 9001 and ISO 14001 certified manufacturing facilities

Description

The 20A Digital MicroDLynx[™] power modules are non-isolated dc-dc converters that can deliver up to 20A of output current. These modules operate over a wide range of input voltage (VIN = 3Vdc-14.4Vdc) and provide a precisely regulated output voltage from 0.6Vdc to 5.5Vdc, programmable via an external resistor and PMBus™ control. Features include a digital interface using the PMBus™ protocol, remote On/Off, adjustable output voltage, over current and over temperature protection. The PMBus™# interface supports a range of commands to both control and monitor the module. The module also includes the Tunable Loop™ feature that allows the user to optimize the dynamic response of the converter to match the load with reduced amount of output capacitance leading to savings on cost and PWB area.

* UL is a registered trademark of Underwriters Laboratories, Inc.

- CSA is a registered trademark of Canadian Standards Association.
- ŧ VDE is a trademark of Verband Deutscher Elektrotechniker e.V.

[#] The PMBus name and logo are registered trademarks of the System Management Interface Forum (SMIF)





^{**} ISO is a registered trademark of the International Organization of Standards

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only, functional operation of the device is not implied at these or any other conditions in excess of those given in the operations sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect the device reliability.

Parameter	Device	Symbol	Min	Max	Unit
Input Voltage	All	V _{IN}	-0.3	15	V
Continuous					
SEQ, SYNC, VS+	All			7	V
CLK, DATA, SMBALERT#	All			3.6	V
Operating Ambient Temperature	All	T _A	-40	105	°C
(see Thermal Considerations section)					
Storage Temperature	All	T _{stg}	-55	125	°C

Electrical Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions.

Parameter	Device	Symbol	Min	Тур	Max	Unit
Operating Input Voltage	All	VIN	3		14.4	Vdc
Maximum Input Current	All	l _{IN,max}			19	Adc
(V_{IN}=3V to 14V, $I_0=I_{0, max}$)						
Input No Load Current ($V_{IN} = 12Vdc$, $I_0 = 0$, module enabled)	V _{0,set} = 0.6 Vdc	I _{IN,No} load		69		mA
	V _{O,set} = 5Vdc	I _{IN,No} load		134		mA
Input Stand-by Current ($V_{IN} = 12Vdc$, module disabled)	All	I _{IN,stand-by}		16.4		mA
Inrush Transient	All	l²t			1	A ² s
Input Reflected Ripple Current, peak-to-peak (5Hz to 20MHz, 1µH source impedance; V _{IN} =0 to 14V, I ₀ = I _{Omax} ; See Test Configurations)	All			50		mAp-p
Input Ripple Rejection (120Hz)	All			-64		dB

Electrical Specifications (continued)

GE

Parameter	Device	Symbo	Min	Тур	Max	Unit
Output Voltage Set-point (with 0.1% tolerance for external resistor used to set output voltage)	All	V _{O, set}	-1.0		+1.0	% V _{O, set}
Output Voltage (Over all operating input voltage, resistive load, and temperature conditions until end of life)	All	V _{O, set}	-3.0	_	+3.0	$\%~V_{\text{O, set}}$
Adjustment Range (selected by an external resistor) (Some output voltages may not be possible depending on the input voltage – see Feature Descriptions Section)	All	Vo	0.6		5.5	Vdc
PMBus Adjustable Output Voltage Range	All	V _o ,adj	-25	0	+25	$%V_{O,set}$
PMBus Output Voltage Adjustment Step Size	All		0.4			%V _{0,set}
Remote Sense Range	All				0.5	Vdc
Output Regulation (for $V_0 \ge 2.5Vdc$)						
Line (V _{IN} =V _{IN, min} to V _{IN, max})	All		± 0.17	± 0.27	±0.4	% V _{O, set}
Load (Io=Io, min to Io, max)	All			_	10	mV
Output Regulation (for V $_{ m O}$ < 2.5Vdc)						
Line (V _{IN} =V _{IN, min} to V _{IN, max})	All			_	5	mV
Load (Io=Io, min to Io, max)	All			_	10	mV
Temperature ($T_{ref}=T_{A, min}$ to $T_{A, max}$)	All			_	0.4	% V _{O, set}
Output Ripple and Noise on nominal output $(V_{IN}=V_{IN, nom} \text{ and } I_{O=IO, min} \text{ to } I_{O, max} \text{ Co} = 0.1 \mu \text{F} // 22 \mu \text{F}$ ceramic capacitors) Peak-to-Peak (5Hz to 20MHz bandwidth)	All			50	100	mV _{pk-pk}
RMS (5Hz to 20MHz bandwidth)	All			20	38	mV _{rms}
External Capacitance ¹						
Without the Tunable Loop™						_
ESR≥1mΩ	All	C _{O, max}	2x47	_	2x47	μF
With the Tunable Loop™					1000	-
ESR ≥ 0.15 mΩ	All	C _{O, max}	2x47	_	1000	μF -
$ESR \ge 10 \text{ m}\Omega$	All	C _{O, max}	2x47	—	10000	μF
Output Current (in either sink or source mode)	All	I _o	0		20	Adc
Output Current Limit Inception (Hiccup Mode) (current limit does not operate in sink mode)	All	Io, lim	110	130	150	% l _{o,max}
Output Short-Circuit Current	All	I _{O, s/c}	1.4	2.5	3.6	Arms
(V₀≤250mV) (Hiccup Mode)						
Efficiency	V _{0,set} = 0.6Vdc	η	76.0	79.1		%
V _{IN} = 12Vdc, T _A =25°C	V _{O, set} = 1.2Vdc	η	84.3	87.1		%
I _O =I _{O, max} , V _O = V _{O,set}	V _{0,set} = 1.8Vdc	η	87.2	90.4		%
	V _{0,set} = 2.5Vdc	η	90.3	92.6		%
	$V_{O,set} = 3.3 Vdc$	η	91.4	93.8		%
	V _{0,set} = 5.0Vdc	η	92.8	95.2		%
Switching Frequency	All	f _{sw}	475	500	525	kHz

¹ External capacitors may require using the new Tunable Loop™ feature to ensure that the module is stable as well as getting the best transient response. See the Tunable Loop™ section for details.

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Electrical Specifications (continued)

Parameter	Device	Symbol	Min	Тур	Мах	Unit
Frequency Synchronization	All					
Synchronization Frequency Range	All		425		600	kHz
High-Level Input Voltage	All	VIH	2.0			V
Low-Level Input Voltage	All	VIL			0.4	V
Input Current, SYNC	All	I _{SYNC}			100	nA
Minimum Pulse Width, SYNC	All	tsync	100			ns
Maximum SYNC rise time	All	t _{sync_sh}	100			ns

General Specifications

Parameter	Device	Min	Тур	Max	Unit
Calculated MTBF (I ₀ =0.8I _{0, max} , T _A =40°C) Telecordia Issue 2 Method 1 Case 3	All		15,455,614		Hours
Weight		4.086 (0.14)	4.54 (0.16)	4.994 (0.18)	g (oz.)

Feature Specifications

Unless otherwise indicated, specifications apply overall operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Device	Symbol	Min	Тур	Max	Unit
On/Off Signal Interface						
(V_IN=V_IN, min to V_IN, max; open collector or equivalent,						
Signal referenced to GND)						
Device code with suffix "4" – Positive Logic (See Ordering Information)						
Logic High (Module ON)						
Input High Current	All	Ін			1	mA
Input High Voltage	All	Vih	2		V _{IN,max}	V
Logic Low (Module OFF)						
Input Low Current	All	lil	_		1	mA
Input Low Voltage	All	VIL	-0.2		0.6	V
Device Code with no suffix – Negative Logic (See Ordering Information)						
(On/OFF pin is open collector/drain logic input with						
external pull-up resistor; signal referenced to GND)						
Logic High (Module OFF)						
Input High Current	All	Ін	-	-	1	mA
Input High Voltage	All	Vih	2	-	V _{IN, max}	Vdc
Logic Low (Module ON)						
Input low Current	All	lı∟	-	-	10	μΑ
Input Low Voltage	All	VIL	-0.2	-	0.6	Vdc

Feature Specifications (cont.)

Parameter	Device	Symbol	Min	Тур	Max	Units
Turn-On Delay and Rise Times						
$(V_{IN}\!\!=\!\!V_{IN,nom,}I_{O}\!\!=\!\!I_{O,max,}V_{O}$ to within ±1% of steady state)						
Case 1: On/Off input is enabled and then input power is applied (delay from instant at which $V_{IN} = V_{IN, min}$ until $V_0 = 10\%$ of $V_{0, set}$)	All	Tdelay	0.8	1.1	1.7	msec
Case 2: Input power is applied for at least one second and then the On/Off input is enabled (delay from instant at which Von/Off is enabled until $V_0 = 10\%$ of $V_{0, set}$)	All	Tdelay	600	700	1800	µsec
Output voltage Rise time (time for V $_0$ to rise from 10% of V $_0$, set to 90% of V $_0$, set)	All	Trise	1.2	1.5	2.7	msec
Output voltage overshoot (T _A = 25°C V _{IN} = V _{IN, min} to V _{IN, max} , lo = lo, min to lo, max) With or without maximum external capacitance					3.0	% V _{O, set}
Over Temperature Protection		T _{ref} -Q1	123	133	143	°C
(See Thermal Considerations section)	All	T _{ref} -Q4	121	131	141	°C
PMBus Over Temperature Warning Threshold *	All	Twarn	120	130	140	°C
Tracking Accuracy (Power-Up: 2V/ms)	All	Vseq –Vo			100	mV
(Power-Down: 2V/ms)	All	Vseq –Vo			100	mV
(V_{IN,min} to V_{IN,max}; I_{O,min} to $I_{O,max}$ VSEQ < Vo)						
Input Undervoltage Lockout						
Turn-on Threshold	All		2.7		2.95	Vdc
Turn-off Threshold	All		2.4		2.75	Vdc
Hysteresis	All		0.05		0.4	Vdc
PMBus Adjustable Input Under Voltage Lockout Thresholds	All		2.5		14	Vdc
Resolution of Adjustable Input Under Voltage Threshold	All				500	mV
PGOOD (Power Good)						
Signal Interface Open Drain, $V_{supply} \leq 5VDC$						
Overvoltage threshold for PGOOD ON	All		103	108	113	%V _{O, set}
Overvoltage threshold for PGOOD OFF	All		100	105	110	%V _{O, set}
Undervoltage threshold for PGOOD ON	All		105	110	115	%V _{O, set}
Undervoltage threshold for PGOOD OFF	All		85	90	95	%V _{O, set}
Pulldown resistance of PGOOD pin	All				50	Ω
Sink current capability into PGOOD pin	All				5	mA

* Over temperature Warning – Warning may not activate before alarm and unit may shutdown before warning

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Digital Interface Specifications

Unless otherwise indicated, specifications apply over all operating input voltage, resistive load, and temperature conditions. See Feature Descriptions for additional information.

Parameter	Conditions	Symbol	Min	Тур	Max	Unit
PMBus Signal Interface Characteristics						
Input High Voltage (CLK, DATA)		Vih	2.1		3.6	V
Input Low Voltage (CLK, DATA)		VIL			0.8	V
Input high level current (CLK, DATA)		Iн	-10		10	μΑ
Input low level current (CLK, DATA)		lı.	-10		10	μA
Output Low Voltage (CLK, DATA, SMBALERT#)	Iout=2mA	Vol			0.4	V
Output high level open drain leakage current (DATA, SMBALERT#)	V _{OUT} =3.6V	I _{ОН}	0		10	μΑ
Pin capacitance		Co		0.7		pF
PMBus Operating frequency range	Slave Mode	Fpmb	10		400	kHz
Data hold time	Receive Mode Transmit Mode	thd:dat	0 300			ns
Data setup time		tsu:dat	250			ns
Measurement System Characteristics						
Read delay time		tdly	153	192	231	μs
Output current measurement range		I _{RNG}	0		26	А
Output current measurement resolution		IRES	62.5			mA
Output current measurement accuracy at 25°C (with $I_{\text{OUT, COR}}$		lacc			±5	%
Output current measurement offset		IOFST			0.1	А
V _{OUT} measurement range		V _{OUT(rng)}	0		5.5	V
V _{OUT} measurement resolution		Vout(res)		15.62 5		mV
V _{OUT} measurement accuracy		Vout, acc	-15		5	%
V _{OUT} measurement offset		V _{OUT(ofst)}	-3		3	%
V _{IN} measurement range		V _{IN(rng)}	0		14.4	V
V _{IN} measurement resolution		V _{IN(res)}		32.5		mV
V _{IN} measurement accuracy		VIN, ACC	-15		5	%
V _{IN} measurement offset		VIN(ofst)	-5.5	-2	1.4	LSB

Z

OUTPUT CURRENT, Io

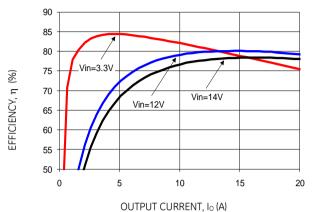
OUTPUT OLTAGE Vo (V) (10mV/div)

Io (A) (10Adiv)

Characteristic Curves

GE

The following figures provide typical characteristics for the 20A Digital MicroDLynx[™] at 0.6Vo and 25°C.



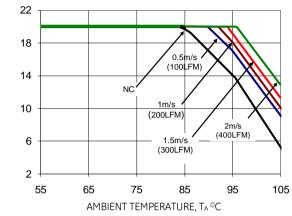
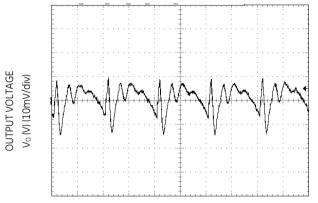


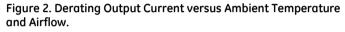
Figure 1. Converter Efficiency versus Output Current.



TIME, t (1µs/div)

OUTPUT CURRENT,

Figure 3. Typical output ripple and noise (Co=2x47µF ceramic, VIN = 12V, Io = Io,max,).



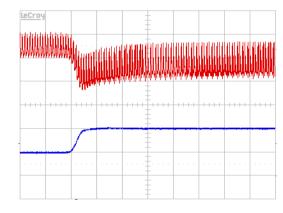




Figure 4. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout= 1x47uF +11x330uF CTune=47nF, RTune=178 ohms

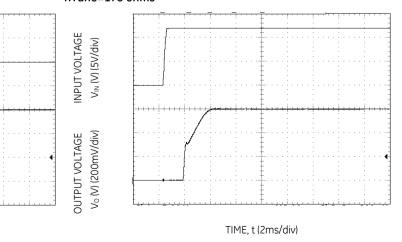


Figure 5. Typical Start-up Using On/Off Voltage (Io = Io,max).

TIME, t (2ms/div)

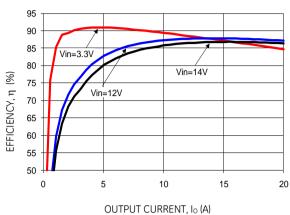
Figure 6. Typical Start-up Using Input Voltage (VIN = 12V, Io = Io,max).

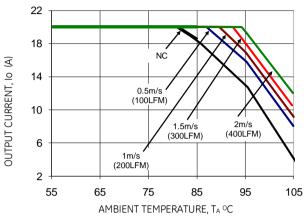
ON/OFF VOLTAGE Von/OFF (V) (5V/div)

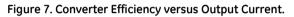
OUTPUT VOLTAGE Vo (V) (200mV/div)

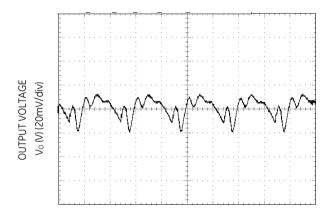
Characteristic Curves

The following figures provide typical characteristics for the 20A Digital MicroDLynx[™] at 1.2Vo and 25°C.





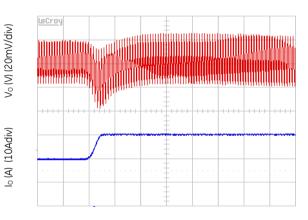




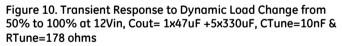
TIME, t (1µs/div)

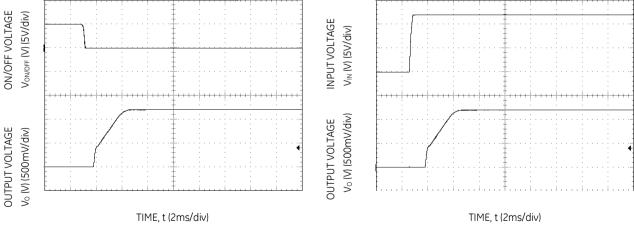
Figure 9. Typical output ripple and noise ($C_0=2x47\mu F$ ceramic, $V_{IN} = 12V$, $I_0 = I_{0,max}$,).

Figure 8. Derating Output Current versus Ambient Temperature and Airflow.





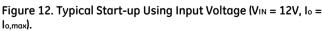




OUTPUT VOLTAGE

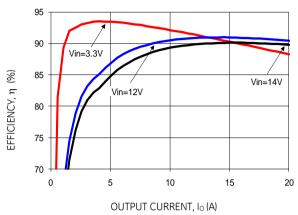
OUTPUT CURRENT,

Figure 11. Typical Start-up Using On/Off Voltage ($I_0 = I_{0,max}$).



Characteristic Curves

The following figures provide typical characteristics for the 20A Digital MicroDLynx[™] at 1.8Vo and 25°C.



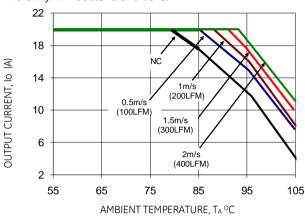
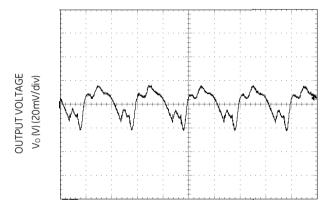


Figure 13. Converter Efficiency versus Output Current.



TIME, t (1µs/div)

Figure 15. Typical output ripple and noise ($C_0=2X47\mu F$ ceramic, $V_{IN} = 12V$, $I_0 = I_{0,max}$,).

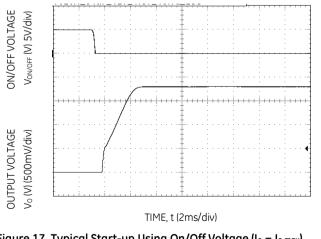
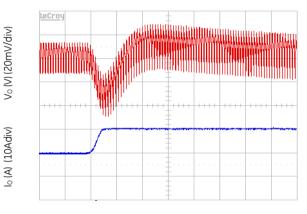
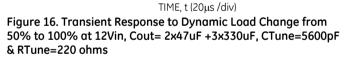
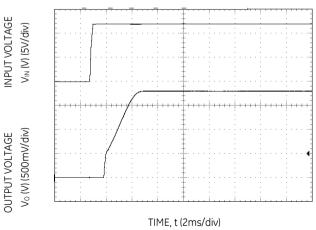


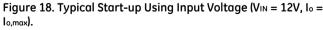
Figure 17. Typical Start-up Using On/Off Voltage ($I_0 = I_{0,max}$).

Figure 14. Derating Output Current versus Ambient Temperature and Airflow.







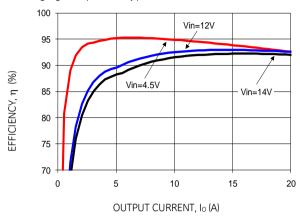


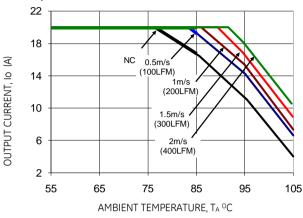
OUTPUT VOLTAGE

OUTPUT CURRENT,

Characteristic Curves

The following figures provide typical characteristics for the 20A Digital MicroDLynx[™] at 2.5Vo and 25°C.







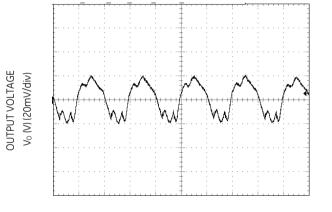
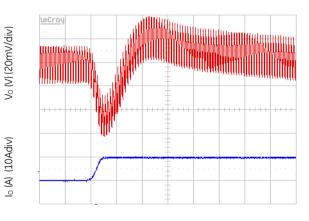
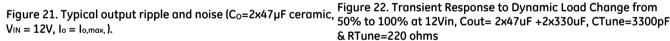




Figure 20. Derating Output Current versus Ambient Temperature and Airflow.

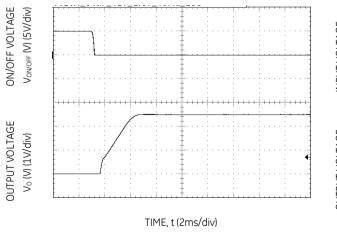






OUTPUT VOLTAGE

OUTPUT CURRENT,





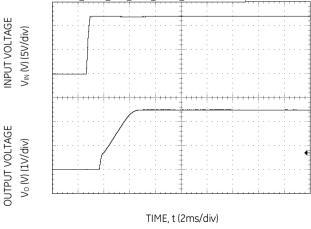
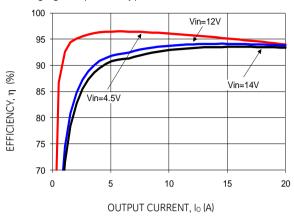
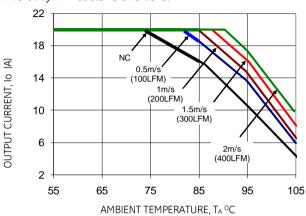


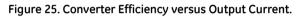
Figure 24. Typical Start-up Using Input Voltage (VIN = 12V, $I_{\rm O}$ = $I_{\rm O,max}$).

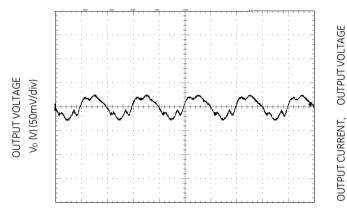
Characteristic Curves

The following figures provide typical characteristics for the 20A Digital MicroDLynx[™] at 3.3Vo and 25°C.









TIME, t (1µs/div)

Figure 27. Typical output ripple and noise ($C_0=2x47\mu F$ ceramic, $V_{IN} = 12V$, $I_0 = I_{0,max}$,).

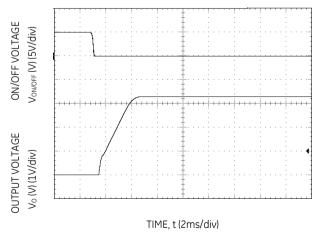
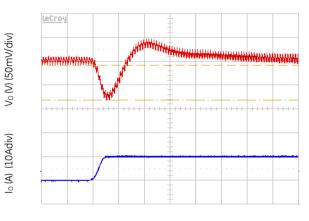


Figure 29. Typical Start-up Using On/Off Voltage ($I_0 = I_{0,max}$).

Figure 26. Derating Output Current versus Ambient Temperature and Airflow.



TIME, t (20µs /div)

Figure 28 Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout= 5x47uF +1x330uF, CTune=2200pF & RTune=220 ohms

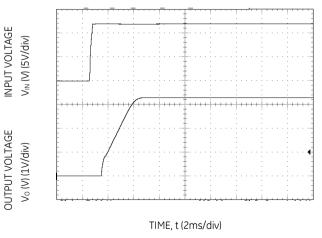
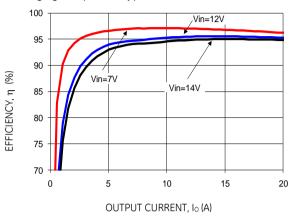
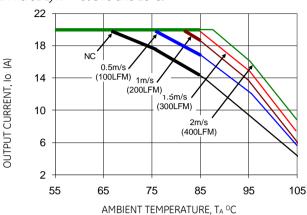


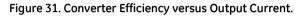
Figure 30. Typical Start-up Using Input Voltage ($V_{IN} = 12V$, $I_0 = I_{0,max}$).

Characteristic Curves

The following figures provide typical characteristics for the 20A Digital MicroDLynx[™] at 5Vo and 25°C.







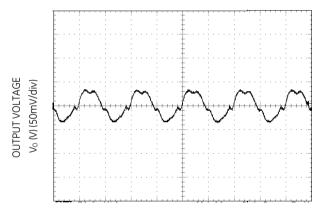
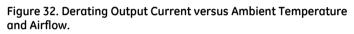




Figure 33. Typical output ripple and noise ($C_0=2x47\mu F$ ceramic, $V_{IN} = 12V$, $I_0 = I_{0,max}$).



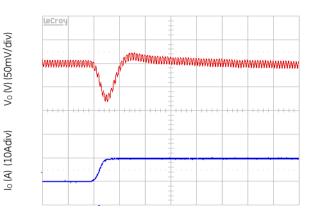
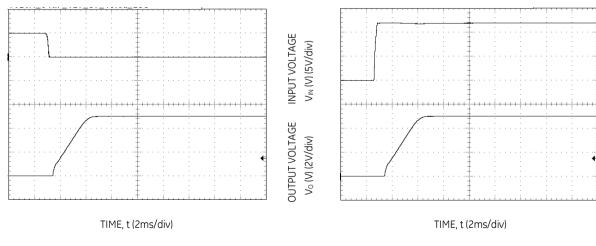




Figure 34. Transient Response to Dynamic Load Change from 50% to 100% at 12Vin, Cout= 8x47uF, CTune=1500pF & RTune=220 ohms



OUTPUT VOLTAGE

OUTPUT CURRENT,



Figure 36. Typical Start-up Using Input Voltage ($V_{IN} = 12V$, $I_0 = I_{0,max}$).

ON/OFF VOLTAGE Von/OFF (V) (5V/div)

OUTPUT VOLTAGE

Vo (V) (2V/div)

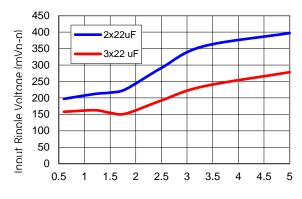
Design Considerations

Input Filtering

GF

The 20A Digital MicroDLynx[™] module should be connected to a low ac-impedance source. A highly inductive source can affect the stability of the module. An input capacitance must be placed directly adjacent to the input pin of the module, to minimize input ripple voltage and ensure module stability.

To minimize input voltage ripple, ceramic capacitors are recommended at the input of the module. Figure 37 shows the input ripple voltage for various output voltages at 20A of load current with $2x22 \ \mu$ F or $3x22 \ \mu$ F ceramic capacitors and an input of 12V.



Output Voltage (Vdc)

Figure 37. Input ripple voltage for various output voltages with 2x22 μF or 3x22 μF ceramic capacitors at the input (20A load). Input voltage is 12V.

Output Filtering

These modules are designed for low output ripple voltage and will meet the maximum output ripple specification with $0.1 \,\mu\text{F}$ ceramic and 2x47 μF ceramic capacitors at the output of the module. However, additional output filtering may be required by the system designer for a number of reasons. First, there may be a need to further reduce the output ripple and noise of the module. Second, the dynamic response characteristics may need to be customized to a particular load step change.

To reduce the output ripple and improve the dynamic response to a step load change, additional capacitance at the output can be used. Low ESR polymer and ceramic capacitors are recommended to improve the dynamic response of the module. Figure 38 provides output ripple information for different external capacitance values at various Vo and a full load current of 20A. For stable operation of the module, limit the capacitance to less than the maximum output capacitance as specified in the electrical specification table. Optimal performance of the module can be achieved by using the Tunable Loop[™] feature described later in this data sheet.

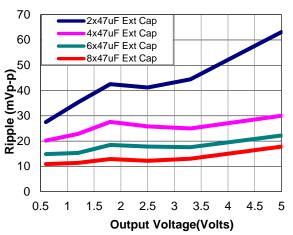


Figure 38. Output ripple voltage for various output voltages with external 2x47 μ F, 4x47 μ F or 6x47 μ F ceramic capacitors at the output (20A load). Input voltage is 12V.

Safety Considerations

For safety agency approval the power module must be installed in compliance with the spacing and separation requirements of the end-use safety agency standards, i.e., UL 60950-1 2nd, CSA C22.2 No. 60950-1-07, DIN EN 60950-1:2006 + A11 (VDE0805 Teil 1 + A11):2009-11; EN 60950-1:2006 + A11:2009-03.

For the converter output to be considered meeting the requirements of safety extra-low voltage (SELV), the input must meet SELV requirements. The power module has extra-low voltage (ELV) outputs when all inputs are ELV.

The UDT020A0X series were tested using an external Littelfuse 456 series fast-acting fuse rated at 30 A, 100 Vdc in the ungrounded input.

20A Digital MicroDLynx™: Non-Isolated DC-DC Power Modules

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Analog Feature Descriptions

Remote On/Off

The module can be turned ON and OFF either by using the ON/OFF pin (Analog interface) or through the PMBus interface (Digital). The module can be configured in a number of ways through the PMBus interface to react to the two ON/OFF inputs:

- Module ON/OFF can be controlled only through the analog interface (digital interface ON/OFF commands are ignored)
- Module ON/OFF can be controlled only through the PMBus interface (analog interface is ignored)
- Module ON/OFF can be controlled by either the analog or digital interface

The default state of the module (as shipped from the factory) is to be controlled by the analog interface only. If the digital interface is to be enabled, or the module is to be controlled only through the digital interface, this change must be made through the PMBus. These changes can be made and written to non-volatile memory on the module so that it is remembered for subsequent use.

Analog On/Off

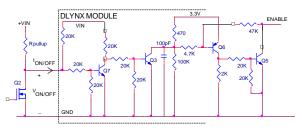
The 20A Digital MicroDLynx[™] power modules feature an On/Off pin for remote On/Off operation. Two On/Off logic options are available. In the Positive Logic On/Off option, (device code suffix "4" – see Ordering Information), the module turns ON during a logic High on the On/Off pin and turns OFF during a logic Low. With the Negative Logic On/Off option, (no device code suffix, see Ordering Information), the module turns OFF during logic High and ON during logic Low. The On/Off signal should be always referenced to ground. For either On/Off logic option, leaving the On/Off pin disconnected will turn the module ON when input voltage is present.

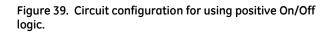
For positive logic modules, the circuit configuration for using the On/Off pin is shown in Figure 39. When the external transistor Q2 is in the OFF state, the internal transistor Q7 is turned ON, which turn Q3 OFF which keeps Q6 OFF and Q5 OFF. This allows the internal PWM #Enable signal to be pulled up by the internal 3.3V, thus turning the module ON. When transistor Q2 is turned ON, the On/Off pin is pulled low, which turns Q7 OFF which turns Q3, Q6 and Q5 ON and the internal PWM #Enable signal is pulled low and the module is OFF. A suggested value for R_{pullup} is $20k\Omega$.

For negative logic On/Off modules, the circuit configuration is shown in Fig. 40. The On/Off pin should be pulled high with an external pull-up resistor (suggested value for the 3V to 14V input range is 20Kohms). When transistor Q2 is in the OFF state, the On/Off pin is pulled high, transistor Q3 is turned ON. This turns Q6 ON, followed by Q5 turning ON which pulls the internal ENABLE low and the module is OFF. To turn the module ON, Q2 is turned ON pulling the On/Off pin low, turning transistor Q3 OFF, which keeps Q6 and Q5 OFF resulting in the PWM Enable pin going high.

Digital On/Off

Please see the Digital Feature Descriptions section.





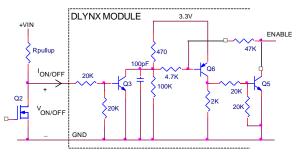


Figure 40. Circuit configuration for using negative On/Off logic.

Monotonic Start-up and Shutdown

The module has monotonic start-up and shutdown behavior for any combination of rated input voltage, output current and operating temperature range.

Startup into Pre-biased Output

The module can start into a prebiased output as long as the prebias voltage is 0.5V less than the set output voltage.

Analog Output Voltage Programming

The output voltage of the module is programmable to any voltage from 0.6dc to 5.5Vdc by connecting a resistor between the Trim and SIG_GND pins of the module. Certain restrictions apply on the output voltage set point depending on the input voltage. These are shown in the Output Voltage vs. Input Voltage Set Point Area plot in Fig. 41. The Upper Limit curve shows that for output voltages lower than 1V, the input voltage must be lower than the maximum of 14.4V. The Lower Limit curve shows that for output voltages higher than 0.6V, the input voltage needs to be larger than

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules 3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

the minimum of 3V..

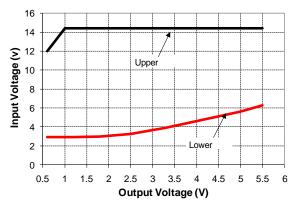
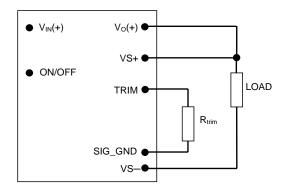


Figure 41. Output Voltage vs. Input Voltage Set Point Area plot showing limits where the output voltage can be set for different input voltages.



Caution – Do not connect SIG_GND to GND elsewhere in the layout

Figure 42. Circuit configuration for programming output voltage using an external resistor.

Without an external resistor between Trim and SIG_GND pins, the output of the module will be 0.6Vdc. To calculate the value of the trim resistor, *Rtrim* for a desired output voltage, should be as per the following equation:

$$Rtrim = \left[\frac{12}{(Vo - 0.6)}\right] k\Omega$$

Rtrim is the external resistor in $k \boldsymbol{\Omega}$

Vo is the desired output voltage.

Table 1 provides Rtrim values required for some common output voltages.

Table 1

Rtrim (KΩ)
Open
40
30
20
13.33
10
6.316
4.444
2.727

Digital Output Voltage Adjustment

Please see the Digital Feature Descriptions section.

Remote Sense

The power module has a Remote Sense feature to minimize the effects of distribution losses by regulating the voltage between the sense pins (VS+ and VS-). The voltage drop between the sense pins and the VOUT and GND pins of the module should not exceed 0.5V.

Analog Voltage Margining

Output voltage margining can be implemented in the module by connecting a resistor, R_{margin-up}, from the Trim pin to the ground pin for margining-up the output voltage and by connecting a resistor, R_{margin-down}, from the Trim pin to output pin for margining-down. Figure 43 shows the circuit configuration for output voltage margining. The POL Programming Tool, available at www.gecriticalpower.com under the Downloads section, also calculates the values of R_{margin-up} and R_{margin-down} for a specific output voltage and % margin. Please consult your local GE technical representative for additional details.

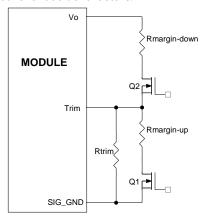


Figure 43. Circuit Configuration for margining Output voltage.

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules

3Vdc –14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Digital Output Voltage Margining

Please see the Digital Feature Descriptions section.

Output Voltage Sequencing

The power module includes a sequencing feature, EZ-SEQUENCE that enables users to implement various types of output voltage sequencing in their applications. This is accomplished via an additional sequencing pin. When not using the sequencing feature, leave it unconnected.

The voltage applied to the SEQ pin should be scaled down by the same ratio as used to scale the output voltage down to the reference voltage of the module. This is accomplished by an external resistive divider connected across the sequencing voltage before it is fed to the SEQ pin as shown in Fig. 44. In addition, a small capacitor (suggested value 100pF) should be connected across the lower resistor R1.

For all DLynx modules, the minimum recommended delay between the ON/OFF signal and the sequencing signal is 10ms to ensure that the module output is ramped up according to the sequencing signal. This ensures that the module soft-start routine is completed before the sequencing signal is allowed to ramp up.

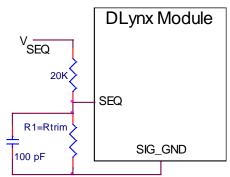


Figure 44. Circuit showing connection of the sequencing signal to the SEQ pin.

When the scaled down sequencing voltage is applied to the SEQ pin, the output voltage tracks this voltage until the output reaches the set-point voltage. The final value of the sequencing voltage must be set higher than the set-point voltage of the module. The output voltage follows the sequencing voltage on a one-to-one basis. By connecting multiple modules together, multiple modules can track their output voltages to the voltage applied on the SEQ pin.

To initiate simultaneous shutdown of the modules, the SEQ pin voltage is lowered in a controlled manner. The output voltage of the modules tracks the voltages below their set-point voltages on a one-to-one basis. A valid input voltage must be maintained until the tracking and output voltages reach ground potential.

Note that in all digital DLynx series of modules, the PMBus Output Undervoltage Fault will be tripped when sequencing is employed. This will be detected using the STATUS_WORD and STATUS_VOUT PMBus commands. In addition, the SMBALERT# signal will be asserted low as occurs for all faults and warnings. To avoid the module shutting down due to the Output Undervoltage Fault, the module must be set to continue operation without interruption as the response to this fault (see the description of the PMBus command VOUT_UV_FAULT_RESPONSE for additional information).

Overcurrent Protection

To provide protection in a fault (output overload) condition, the unit is equipped with internal current-limiting circuitry and can endure current limiting continuously. At the point of current-limit inception, the unit enters hiccup mode. The unit operates normally once the output current is brought back into its specified range.

Digital Adjustable Overcurrent Warning

Please see the Digital Feature Descriptions section.

Overtemperature Protection

To provide protection in a fault condition, the unit is equipped with a thermal shutdown circuit. The unit will shut down if the over-temperature threshold of 128° C ~ 130° C (typ) is exceeded at the thermal reference point T_{ref}.Please refer to Electrical characteristic table, over-temperature section on page 5. Once the unit goes into thermal shutdown it will then wait to cool before attempting to restart.

Digital Temperature Status via PMBus

Please see the Digital Feature Descriptions section.

Digitally Adjustable Output Over and Under Voltage Protection

Please see the Digital Feature Descriptions section.

Input Undervoltage Lockout

At input voltages below the input undervoltage lockout limit, the module operation is disabled. The module will begin to operate at an input voltage above the undervoltage lockout turn-on threshold.

Digitally Adjustable Input Undervoltage Lockout

Please see the Digital Feature Descriptions section.

Digitally Adjustable Power Good Thresholds

Please see the Digital Feature Descriptions section.

20A Digital MicroDLynx™: Non-Isolated DC-DC Power Modules

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Synchronization

The module switching frequency can be synchronized to a signal with an external frequency within a specified range. Synchronization can be done by using the external signal applied to the SYNC pin of the module as shown in Fig. 45, with the converter being synchronized by the rising edge of the external signal. The Electrical Specifications table specifies the requirements of the external SYNC signal. If the SYNC pin is not used, the module should free run at the default switching frequency. If synchronization is not being used, connect the SYNC pin to GND.

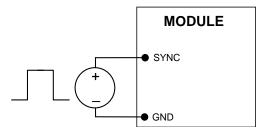


Figure 45. External source connections to synchronize switching frequency of the module.

Measuring Output Current, Output Voltage and Input Voltage

Please see the Digital Feature Descriptions section.

Dual Layout

Identical dimensions and pin layout of Analog and Digital MicroDLynx modules permit migration from one to the other without needing to change the layout. In both cases the trim resistor is connected between trim and signal ground. The output of the analog module cannot be trimmed down to 0.45V

Power Good

The module provides a Power Good (PGOOD) signal that is implemented with an open-drain output to indicate that the output voltage is within the regulation limits of the power module. The PGOOD signal will be de-asserted to a low state if any condition such as overtemperature, overcurrent or loss of regulation occurs that would result in the output voltage going $\pm 10\%$ outside the setpoint value. The PGOOD terminal can be connected through a pullup resistor (suggested value $100K\Omega$) to a source of 5VDC or lower.

Tunable Loop™

The module has a feature that optimizes transient response of the module called Tunable $Loop^{TM}$.

External capacitors are usually added to the output of the module for two reasons: to reduce output ripple and noise (see Figure 38) and to reduce output voltage deviations from the steady-state value in the presence of dynamic load current changes. Adding external capacitance however affects the voltage control loop of the module, typically causing the loop to slow down with sluggish response. Larger values of external capacitance could also cause the module to become unstable.

The Tunable LoopTM allows the user to externally adjust the voltage control loop to match the filter network connected to the output of the module. The Tunable LoopTM is implemented by connecting a series R-C between the VS+ and TRIM pins of the module, as shown in Fig. 46. This R-C allows the user to externally adjust the voltage loop feedback compensation of the module.

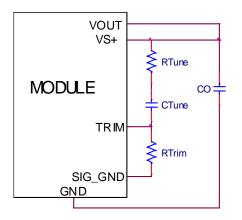


Figure. 46. Circuit diagram showing connection of RTUME and CTUNE to tune the control loop of the module.

Recommended values of R_{TUNE} and C_{TUNE} for different output capacitor combinations are given in Tables 2 and 3. Table 3 shows the recommended values of R_{TUNE} and C_{TUNE} for different values of ceramic output capacitors up to 1000uF that might be needed for an application to meet output ripple and noise requirements. Selecting R_{TUNE} and C_{TUNE} according to Table 3 will ensure stable operation of the module.

In applications with tight output voltage limits in the presence of dynamic current loading, additional output capacitance will be required. Table 3 lists recommended values of R_{TUNE} and C_{TUNE} in order to meet 2% output voltage deviation limits for some common output voltages in the presence of a 10A to 20A step change (50% of full load), with an input voltage of 12V.

Please contact your GE technical representative to obtain more details of this feature as well as for guidelines on how to select the right value of external R-C to tune the module for best transient performance and stable operation for other output capacitance values.

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Table 2. General recommended values of of R_{TUNE} and C_{TUNE} for Vin=12V and various external ceramic capacitor combinations.

Со	2x47µF	4x47μF	6x47μF	10x47μF	20x47µF
R _{TUNE}	330	330	270	220	180
CTUNE	47pF	560pF	1200pF	2200pF	4700pF

Table 3. Recommended values of R_{TUNE} and C_{TUNE} to obtain transient deviation of 2% of Vout for a 10A step load with Vin=12V.

Vo	5V	3.3V	2.5V	1.8V	1.2V	0.6V
Co	8x47µF	5x47μF + 1x330μF Polymer	2x47µF + 2x330µF Polymer	2x47µF + 3x330µF Polymer	1x47µF + 5x330µF Polymer	1x47μF + 11x330μF Polymer
R _{TUNE}	220	220	220	220	180	180
CTUNE	1500pF	2200pF	3300pF	5600pF	10nF	47nF
ΔV	100mV	64mV	49mV	36mV	24mV	12mV

Note: The capacitors used in the Tunable Loop tables are 47 $\mu\text{F}/3$ m Ω ESR ceramic and 330 $\mu\text{F}/12$ m Ω ESR polymer capacitors.

Digital Feature Descriptions

PMBus Interface Capability

GF

The 20A Digital MicroDLynx[™] power modules have a PMBus interface that supports both communication and control. The PMBus Power Management Protocol Specification can be obtained from www.pmbus.org. The modules support a subset of version 1.1 of the specification (see Table 6 for a list of the specific commands supported). Most module parameters can be programmed using PMBus and stored as defaults for later use.

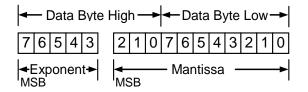
All communication over the module PMBus interface must support the Packet Error Checking (PEC) scheme. The PMBus master must generate the correct PEC byte for all transactions, and check the PEC byte returned by the module.

The module also supports the SMBALERT# response protocol whereby the module can alert the bus master if it wants to talk. For more information on the SMBus alert response protocol, see the System Management Bus (SMBus) specification.

The module has non-volatile memory that is used to store configuration settings. Not all settings programmed into the device are automatically saved into this non-volatile memory, only those specifically identified as capable of being stored can be saved (see Table 6 for which command parameters can be saved to non-volatile storage).

PMBus Data Format

For commands that set thresholds, voltages or report such quantities, the module supports the "Linear" data format among the three data formats supported by PMBus. The Linear Data Format is a two byte value with an 11-bit, two's complement mantissa and a 5-bit, two's complement exponent. The format of the two data bytes is shown below:



The value is of the number is then given by

Value = Mantissa x 2 ^{Exponent}

PMBus Addressing

The power module can be addressed through the PMBus using a device address. The module has 64 possible addresses (0 to 63 in decimal) which can be set using resistors connected from the ADDR0 and ADDR1 pins to GND. Note that some of these addresses (0, 1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 11 12, 40, 44, 45, 55 in decimal) are reserved according to the SMBus specifications and may not be useable. The address is set in the form of two octal (0 to 7) digits, with each pin setting one digit. The ADDR1 pin sets the high order digit and ADDR0 sets the low order digit. The resistor values suggested for each digit are shown in Table 4 (1% tolerance resistors are recommended). Note that if either address resistor value is outside the range specified in Table 4, the module will respond to address 127.

	Table 4
Digit	Resistor Value (KΩ)
0	10
1	15.4
2	23.7
3	36.5
4	54.9
5	84.5
6	130
7	200

The user must know which I²C addresses are reserved in a system for special functions and set the address of the module to avoid interfering with other system operations. Both 100kHz and 400kHz bus speeds are supported by the module. Connection for the PMBus interface should follow the High Power DC specifications given in section 3.1.3 in the SMBus specification V2.0 for the 400kHz bus speed or the Low Power DC specifications in section 3.1.2. The complete SMBus specification is available from the SMBus web site, <u>smbus.org</u>.

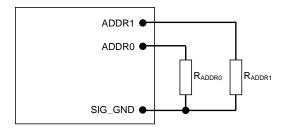


Figure 47. Circuit showing connection of resistors used to set the PMBus address of the module.

PMBus Enabled On/Off

The module can also be turned on and off via the PMBus interface. The OPERATION command is used to actually turn the module on and off via the PMBus, while the ON_OFF_CONFIG command configures the combination of analog ON/OFF pin input and PMBus commands needed to turn the module on and off. Bit [7] in the OPERATION command data byte enables the module, with the following functions:

- 0 : Output is disabled
- 1 : Output is enabled

This module uses the lower five bits of the ON_OFF_CONFIG data byte to set various ON/OFF options as follows:

Bit Position	4	3	2	1	0
Access	r/w	r/w	r/w	r/w	r
Function	PU	CMD	CPR	POL	CPA
Default Value	1	0	1	1	1

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules 3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

PU: Sets the default to either operate any time input power is present or for the ON/OFF to be controlled by the analog

 ON/OFF input and the <code>PMBus</code> <code>OPERATION</code> command. This bit is used together with the CP, CMD and ON bits to determine startup.

Bit Value	Action
0	Module powers up any time power is present regardless of state of the analog ON/OFF pin
1	Module does not power up until commanded by the analog ON/OFF pin and the OPERATION command as programmed in bits [2:0] of the ON_OFF_CONFIG register.

CMD: The CMD bit controls how the device responds to the OPERATION command.

Bit Value	Action
0	Module ignores the ON bit in the OPERATION command
1	Module responds to the ON bit in the OPERATION command

CPR: Sets the response of the analog ON/OFF pin. This bit is used together with the CMD, PU and ON bits to determine startup.

Bit Value	Action
0	Module ignores the analog ON/OFF pin, i.e. ON/OFF is only controlled through the PMBUS via the OPERATION command
1	Module requires the analog ON/OFF pin to be asserted to start the unit

PMBus Adjustable Soft Start Rise Time

The soft start rise time can be adjusted in the module via PMBus. When setting this parameter, make sure that the charging current for output capacitors can be delivered by the module in addition to any load current to avoid nuisance tripping of the overcurrent protection circuitry during startup. The TON_RISE command sets the rise time in ms, and allows choosing soft start times between 600µs and 9ms, with possible values listed in Table 5. Note that the exponent is fixed at -4 (decimal) and the upper two bits of the mantissa are also fixed at 0.

Rise Time	Exponent	Mantissa
600µs	11100	0000001010
900µs	11100	0000001110
1.2ms	11100	00000010011
1.8ms	11100	00000011101
2.7ms	11100	00000101011
4.2ms	11100	00001000011
6.0ms	11100	00001100000
9.0ms	11100	00010010000

Table 5

Output Voltage Adjustment Using the PMBus

The VOUT_SCALE_LOOP parameter is important for a number of PMBus commands related to output voltage trimming, margining, over/under voltage protection and the PGOOD thresholds. The output voltage of the module is set as the combination of the voltage divider formed by RTrim and a $20k\Omega$ upper divider resistor inside the module, and the internal reference voltage of the module. The reference voltage V_{REF} is nominally set at 600mV, and the output regulation voltage is then given by

$$V_{OUT} = \left[\frac{20000 + RTrim}{RTrim}\right] \times V_{REF}$$

Hence the module output voltage is dependent on the value of RTrim which is connected external to the module. The information on the output voltage divider ratio is conveyed to the module through the VOUT_SCALE_LOOP parameter which is calculated as follows:

$$VOUT_SCALE_LOOP = \frac{RTrim}{20000 + RTrim}$$

The VOUT_SCALE_LOOP parameter is specified using the "Linear" format and two bytes. The upper five bits [7:3] of the high byte are used to set the exponent which is fixed at -9 (decimal). The remaining three bits of the high byte [2:0] and the eight bits of the lower byte are used for the mantissa. The default value of the mantissa is 0010000000 corresponding to 256 (decimal), corresponding to a divider ratio of 0.5. The maximum value of the mantissa is 512 corresponding to a divider ratio of 1. Note that the resolution of the VOUT_SCALE_LOOP command is 0.2%.

When PMBus commands are used to trim or margin the output voltage, the value of V_{REF} is what is changed inside the module, which in turn changes the regulated output voltage of the module.

The nominal output voltage of the module can be adjusted with a minimum step size of 0.4% over a $\pm 25\%$ range from nominal using the VOUT_TRIM command over the PMBus.

The VOUT_TRIM command is used to apply a fixed offset voltage to the output voltage command value

using the "Linear" mode with the exponent fixed at –10 (decimal). The value of the offset voltage is given by

$V_{OUT(offset)} = VOUT _TRIM \times 2^{-10}$

This offset voltage is added to the voltage set through the divider ratio and nominal V_{REF} to produce the trimmed output voltage. The valid range in two's complement for this command is -4000h to 3fffh. The high order two bits of the high byte must both be either 0 or 1. If a value outside of the +/-25% adjustment range is given with this command, the module will set it's output voltage to the nominal value (as if VOUT_TRIM had been set to 0), assert SMBALRT#, set the CML bit in STATUS_BYTE and the invalid data bit in STATUS_CML.

20A Digital MicroDLynx[™]: Non-Isolated DC-DC Power Modules

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Output Voltage Margining Using the PMBus

The module can also have its output voltage margined via PMBus commands. The command VOUT_MARGIN_HIGH sets the margin high voltage, while the command VOUT_MARGIN_LOW sets the margin low voltage. Both the VOUT_MARGIN_HIGH and VOUT_MARGIN_LOW commands use the "Linear" mode with the exponent fixed at -10 (decimal). Two bytes are used for the mantissa with the upper bit [7] of the high byte fixed at 0. The actual margined output voltage is a combination of the VOUT_MARGIN_HIGH or VOUT_MARGIN_LOW and the VOUT_TRIM values as shown below.

 $V_{OUT(MH)} =$

 $(VOUT _MARGIN _HIGH + VOUT _TRIM) \times 2^{-10}$

 $V_{OUT(ML)} =$

 $(VOUT _ MARGIN _ LOW + VOUT _ TRIM) \times 2^{-10}$

Note that the sum of the margin and trim voltages cannot be outside the ±25% window around the nominal output voltage. The data associated with VOUT_MARGIN_HIGH and VOUT_MARGIN_LOW can be stored to non-volatile memory using the STORE_DEFAULT_ALL command.

The module is commanded to go to the margined high or low voltages using the OPERATION command. Bits [5:2] are used to enable margining as follows:

- 00XX : Margin Off
- 0101 : Margin Low (Ignore Fault)
- 0110 : Margin Low (Act on Fault)
- 1001 : Margin High (Ignore Fault)
- 1010 : Margin High (Act on Fault)

PMBus Adjustable Overcurrent Warning

The module can provide an overcurrent warning via the PMBus. The threshold for the overcurrent warning can be set using the parameter IOUT_OC_WARN_LIMIT. This command uses the "Linear" data format with a two byte data word where the upper five bits [7:3] of the high byte represent the exponent and the remaining three bits of the high byte [2:0] and the eight bits in the low byte represent the mantissa. The exponent is fixed at –1 (decimal). The

upper five bits of the mantissa are fixed at 0 while the lower six bits are programmable. For production codes after April 2013, the value for IOUT_OC_WARN_LIMIT will be fixed at 25A. For earlier production codes the actual value for IOUT_OC_WARN_LIMIT will vary from module to module due to calibration during production testing. The resolution of this warning limit is 500mA. The value of the IOUT_OC_WARN_LIMIT can be stored to non-volatile memory using the STORE_DEFAULT_ALL command.

Temperature Status via PMBus

The module can provide information related to temperature of the module through the STATUS_TEMPERATURE command. The command returns information about whether the pre-set over temperature fault threshold and/or the warning threshold have been exceeded.

PMBus Adjustable Output Over and Under Voltage Protection

The module has output over and under voltage protection capability. The PMBus command VOUT_OV_FAULT_LIMIT is used to set the output over voltage threshold from four possible values: 108%, 110%, 112% or 115% of the commanded output voltage. The command VOUT_UV_FAULT_LIMIT sets the threshold that causes an output under voltage fault and can also be selected from four possible values: 92%, 90%, 88% or 85%. The default values are 112% and 88% of commanded output voltage. Both commands use two data bytes formatted as two's complement binary integers. The "Linear" mode is used with the exponent fixed to –10 (decimal) and the effective over or under voltage trip points given by:

 $V_{OUT(OV_REQ)} = (VOUT_OV_FAULT_LIMIT) \times 2^{-10}$

 $V_{OUT(UV_REQ)} = (VOUT_UV_FAULT_LIMIT) \times 2^{-10}$

Values within the supported range for over and undervoltage detection thresholds will be set to the nearest fixed percentage. Note that the correct value for VOUT_SCALE_LOOP must be set in the module for the correct over or under voltage trip points to be calculated.

In addition to adjustable output voltage protection, the 12A Digital Pico DLynxTM module can also be programmed for the response to the fault. The VOUT_OV_FAULT RESPONSE and VOUT_UV_FAULT_RESPONSE commands specify the response to the fault. Both these commands use a single data byte with the possible options as shown below.

- 1. Continue operation without interruption (Bits [7:6] = 00, Bits [5:3] = xxx)
- Continue for four switching cycles and then shut down if the fault is still present, followed by no restart or continuous restart (Bits [7:6] = 01, Bits [5:3] = 000 means no restart, Bits [5:3] = 111 means continuous restart)
- 3. Immediate shut down followed by no restart or continuous restart (Bits [7:6] = 10, Bits [5:3] = 000 means no restart, Bits [5:3] = 111 means continuous restart).
- 4. Module output is disabled when the fault is present and the output is enabled when the fault no longer exists (Bits [7:6] = 11, Bits [5:3] = xxx).

Note that separate response choices are possible for output over voltage or under voltage faults.

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules 3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

PMBus Adjustable Input Undervoltage Lockout

The module allows adjustment of the input under voltage lockout and hysteresis. The command VIN_ON allows setting the input voltage turn on threshold, while the VIN_OFF command sets the input voltage turn off threshold. For the VIN_ON command, possible values are 2.75V, and 3V to 14V in 0.5V steps. For the VIN_OFF command, possible values are 2.5V to 14V in 0.5V steps. If other values are entered for either command, they will be mapped to the closest of the allowed values.

Both the VIN_ON and VIN_OFF commands use the "Linear" format with two data bytes. The upper five bits represent the exponent (fixed at -2) and the remaining 11 bits represent the mantissa. For the mantissa, the four most significant bits are fixed at 0.

Power Good

The module provides a Power Good (PGOOD) signal that is implemented with an open-drain output to indicate that the output voltage is within the regulation limits of the power module. The PGOOD signal will be de-asserted to a low state if any condition such as overtemperature, overcurrent or loss of regulation occurs that would result in the output voltage going outside the specified thresholds. The PGOOD thresholds are user selectable via the PMBus (the default values are as shown in the Feature Specifications Section). Each threshold is set up symmetrically above and below the nominal value. The POWER_GOOD_ON command sets the output voltage level above which PGOOD is asserted (lower threshold). For example, with a 1.2V nominal output voltage, the POWER GOOD ON threshold can set the lower threshold to 1.14 or 1.1V. Doing this will automatically set the upper thresholds to 1.26 or 1.3V.

The POWER_GOOD_OFF command sets the level below which the PGOOD command is de-asserted. This command also sets two thresholds symmetrically placed around the nominal output voltage. Normally, the POWER_GOOD_ON threshold is set higher than the POWER_GOOD_OFF threshold.

Both POWER_GOOD_ON and POWER_GOOD_OFF commands use the "Linear" format with the exponent fixed at –10 (decimal). The two thresholds are given by

 $V_{OUT(PGOOD_ON)} = (POWER_GOOD_ON) \times 2^{-10}$

 $V_{OUT(PGOOD_OFF)} = (POWER_GOOD_OFF) \times 2^{-10}$

Both commands use two data bytes with bit [7] of the high byte fixed at 0, while the remaining bits are r/w and used to set the mantissa using two's complement representation. Both commands also use the **The** VOUT_SCALE_LOOP parameter so it must be set correctly. The default value of POWER_GOOD_ON is set at 1.1035V and that of the POWER_GOOD_OFF is set at 1.08V. The values associated with these commands can be stored in non-volatile memory using the STORE_DEFAULT_ALL command. PGOOD terminal can be connected through a pullup resistor (suggested value $100K\Omega$) to a source of 5VDC or lower.

Measurement of Output Current, Output Voltage and Input Voltage

The module is capable of measuring key module parameters such as output current and voltage and input voltage and providing this information through the PMBus interface. Roughly every 200µs, the module makes 16 measurements each of output current, voltage and input voltage. Average values of each of these measurements are then calculated and placed in the appropriate registers. These values in the registers can then be read using the PMBus interface.

Measuring Output Current Using the PMBus

The module measures current by using the inductor winding resistance as a current sense element. The inductor winding resistance is then the current gain factor used to scale the measured voltage into a current reading. This gain factor is the argument of the IOUT_CAL_GAIN command, and consists of two bytes in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at –15 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa. During manufacture, each module is calibrated by measuring and storing the current gain factor into non-volatile storage.

The current measurement accuracy is also improved by each module being calibrated during manufacture with the offset in the current reading. The IOUT_CAL_OFFSET command is used to store and read the current offset. The argument for this command consists of two bytes composed of a 5-bit exponent (fixed at -4d) and a 11-bit mantissa. This command has a resolution of 62.5mA and a range of -4000mA to +3937.5mA.

The READ_IOUT command provides module average output current information. This command only supports positive or current sourced from the module. If the converter is sinking current a reading of 0 is provided. The READ_IOUT command returns two bytes of data in the linear data format. The exponent uses the upper five bits [7:3] of the high data byte in two-s complement format and is fixed at – 4 (decimal). The remaining 11 bits in two's complement binary format represent the mantissa with the 11th bit fixed at 0 since only positive numbers are considered valid.

Note that the current reading provided by the module is not corrected for temperature. The temperature corrected current reading for module temperature T_{Module} can be estimated using the following equation

$$I_{OUT,CORR} = \frac{I_{READ_OUT}}{1 + [(T_{IND} - 30) \times 0.00393]}$$

where I_{OUT_CORR} is the temperature corrected value of the current measurement, I_{READ_OUT} is the module current measurement value, T_{IND} is the temperature of the inductor winding on the module. Since it may be difficult to measure

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules 3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

 $T_{\text{IND,}}$ it may be approximated by an estimate of the module temperature.

Measuring Output Voltage Using the PMBus

The module can provide output voltage information using the READ_VOUT command. The command returns two bytes of data all representing the mantissa while the exponent is fixed at -10 (decimal).

During manufacture of the module, offset and gain correction values are written into the non-volatile memory of the module. The command VOUT_CAL_OFFSET can be used to read and/or write the offset (two bytes consisting of a 16-bit mantissa in two's complement format) while the exponent is always fixed at -10 (decimal). The allowed range for this offset correction is -125 to 124mV. The command VOUT_CAL_GAIN can be used to read and/or write the gain correction - two bytes consisting of a five-bit exponent (fixed at -8) and a 11-bit mantissa. The range of this correction factor is -0.125 to +0.121, with a resolution of 0.004. The corrected output voltage reading is then given by:

$$\begin{split} V_{OUT}(Final) &= \\ [V_{OUT}(Initial) \times (1 + VOUT _ CAL _ GAIN)] \cdot \\ &+ VOUT _ CAL _ OFFSET \end{split}$$

Measuring Input Voltage Using the PMBus

The module can provide output voltage information using the READ_VIN command. The command returns two bytes of data in the linear format. The upper five bits [7:3] of the high data form the two's complement representation of the exponent which is fixed at -5 (decimal). The remaining 11 bits are used for two's complement representation of the mantissa, with the 11th bit fixed at zero since only positive numbers are valid.

During module manufacture, offset and gain correction values are written into the non-volatile memory of the module. The command VIN_CAL_OFFSET can be used to read and/or write the offset - two bytes consisting of a fivebit exponent (fixed at -5) and a11-bit mantissa in two's complement format. The allowed range for this offset correction is -2to 1.968V, and the resolution is 32mV. The command VIN_CAL_GAIN can be used to read and/or write the gain correction - two bytes consisting of a five-bit exponent (fixed at -8) and a 11-bit mantissa. The range of this correction factor is -0.125 to +0.121, with a resolution of 0.004. The corrected output voltage reading is then given by:

 $V_{IN}(Final) = [V_{IN}(Initial) \times (1 + VIN _ CAL _ GAIN)] + VIN _ CAL _ OFFSET$

Reading the Status of the Module using the PMBus

The module supports a number of status information commands implemented in PMBus. However, not all features are supported in these commands. A 1 in the bit position indicates the fault that is flagged. STATUS_BYTE : Returns one byte of information with a summary of the most critical device faults.

Bit Position	Flag	Default Value
7	Х	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

STATUS_WORD: Returns two bytes of information with a summary of the module's fault/warning conditions.

Bit Position	Flag	Default Value
7	X	0
6	OFF	0
5	VOUT Overvoltage	0
4	IOUT Overcurrent	0
3	VIN Undervoltage	0
2	Temperature	0
1	CML (Comm. Memory Fault)	0
0	None of the above	0

High Byte

Bit Position	Flag	Default Value
7	VOUT fault or warning	0
6	IOUT fault or warning	0
5	Х	0
4	×	0
3	POWER_GOOD# (is negated)	0
2	X	0
1	X	0
0	X	0

STATUS_VOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	VOUT OV Fault	0
6	Х	0
5	Х	0
4	VOUT UV Fault	0
3	Х	0
2	Х	0
1	X	0
0	Х	0

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

STATUS_IOUT : Returns one byte of information relating to the status of the module's output voltage related faults.

Bit Position	Flag	Default Value
7	IOUT OC Fault	0
6	Х	0
5	IOUT OC Warning	0
4	Х	0
3	Х	0
2	Х	0
1	X	0
0	Х	0

STATUS_TEMPERATURE : Returns one byte of information relating to the status of the module's temperature related faults.

Bit Position	Flag	Default Value
7	OT Fault	0
6	OT Warning	0
5	Х	0
4	Х	0
3	Х	0
2	Х	0
1	X	0
0	Х	0

STATUS_CML : Returns one byte of information relating to the status of the module's communication related faults.

Bit Position	Flag	Default Value
7	Invalid/Unsupported Command	0
6	Invalid/Unsupported Command	0
5	Packet Error Check Failed	0
4	Х	0
3	Х	0
2	Х	0
1	Other Communication Fault	0
0	Х	0

MFR_VIN_MIN : Returns minimum input voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -2, and lower 11 bits are mantissa in two's complement format – fixed at 12)

MFR_VOUT_MIN : Returns minimum output voltage as two data bytes of information in Linear format (upper five bits are exponent – fixed at -10, and lower 11 bits are mantissa in two's complement format – fixed at 614)

MFR_SPECIFIC_00: Returns information related to the type of module. Bits [7:2] in the Low Byte indicate the module type (000010 corresponds to the UDT020 series of module). Bits 1:0 in the High Byte are used to indicate the manufacturer ID, with 00 reserved for GE.

Low Byte						
Bit Position	Flag	Default Value				
7:2	Module Name	000010				
1:0	Reserved	10				

High Byte

Bit Position	Flag	Default Value
7:0	Module Revision Number	None
1:0	Manufacturer ID	00

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Summary of Supported PMBus Commands

Please refer to the PMBus 1.1 specification for more details of these commands.

Table 6

01 OPERATION Turn Module on or off. Also used to margin the output voltage 01 OPERATION Imagined Binory Uraggned Binory 02 OR_OFF_CONFIG Configures the OWOFF functionality as a combination of analog ON/OFF pin and PMBus cammonds. Yes 02 OR_OFF_CONFIG Configures the OWOFF functionality as a combination of analog ON/OFF pin and PMBus cammonds. Yes 03 CLEAR_FAULTS Clear any fault bits that may have been set, also releases the SMBALERT# signal if the device has been asserting it. Yes 10 WRITE_PROTECT Clear any fault bits that may have been set, also releases the SMBALERT# signal if the device has been asserting it. Yes 10 WRITE_PROTECT Clear any fault bits that may have been set, also releases the solule in the data byte into non-volidite immory VERMONI on the module. Yes 10 WRITE_PROTECT Uraggned Binory Bit Position 7 To State X X	Hex Code	Command			Bri	ief Desc	ription					Non-Volatile Memory Storage
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10 WRITE_PROTECT BitS: 0 - Enables all writes as permitted in bitS or bit7 YES 1 - Disables all writes except the WRITE_PROTECT, OPERATION and ON_OFF_CONFIG bit is don bit7 must be 0) Bit 6: 0 - Enables all writes except the WRITE_PROTECT and OPERATION commands (bits and bit7 must be 0) Bit 7: 0 - Enables all writes as permitted in bit5 or bit7 1 - Disables all writes except for the WRITE_PROTECT command (bit5 and bit6 must be 0) Bit7: 0 - Enables all writes as permitted in bit5 or bit6 11 STORE_DEFAULT_ALL Copies all current register settings in the module into non-volatile memory (EEPROM) on the module. Takes about 50ms for the command to execute. 12 RESTORE_DEFAULT_ALL Restores all current register settings in the module from values in the module non-volatile memory (EEPROM) 13 STORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) Bit Position 7 6 5 4 3 2 1 0 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 1 0 0												
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Bit 6: 0 - Enables all writes as permitted in bits or bit7 1 - Disables all writes except for the WRITE_PROTECT and OPERATION commands (bits and bit7 must be 0) Bit7: 0 - Enables all writes as permitted in bit5 or bit6 1 - Disables all writes except for the WRITE_PROTECT command (bit5 and bit7 must be 0) Bit7: 0 - Enables all writes except for the WRITE_PROTECT command (bit5 and bit6 must be 0) 11 STORE_DEFAULT_ALL Copies all current register settings in the module into non-volatile memory (EEPROM) on the module. Takes about 50ms for the command to execute. 12 RESTORE_DEFAULT_ALL Restores all current register settings in the module from values in the module non-volatile memory (EEPROM) 13 STORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM)			1 – Disables all	1 – Disables all writes except the WRITE_PROTECT, OPERATION								
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20 VOUT_MODE DeFRATION commands (bit5 and bit7 must be 0) Bit7: 0 - Enables all writes as permitted in bit5 or bit6 1 - Disables all writes except for the WRITE_PROTECT command (bit5 and bit6 must be 0) 11 STORE_DEFAULT_ALL Copies all current register settings in the module into non-volatile memory (EEPROM) on the module. Takes about 50ms for the command to execute. 12 RESTORE_DEFAULT_ALL Restores all current register settings in the module form values in the module non-volatile memory (EEPROM) 13 STORE_DEFAULT_CODE Copies the current register setting in the module whose command code matches the value in the data byte into non-volatile memory (EEPROM) on the module 14 RESTORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 Access W W W W W W W W W W 14 RESTORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 Access W W W W W W W W W W W W W 20 VOUT_MODE Bit Position 7 6 5 4 3 2 1 0 Access W W W W W W W W W W W W W 20 VOUT_MODE Bit Position 7 6 5 4 3 2 1 0 Access W W W W W W W W W W W W		1 – Disables all writes except for the WRITE_PROTECT and										
1 - Disables all writes except for the WRITE_PROTECT command (bits and bit6 must be 0) 11 STORE_DEFAULT_ALL Copies all current register settings in the module into non-volatile memory (EEPROM) on the module. Takes about 50ms for the command to execute. 12 RESTORE_DEFAULT_ALL Restores all current register settings in the module from values in the module non-volatile memory (EEPROM) 13 STORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte into non-volatile memory (EEPROM) on the module 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module non-volatile memory (EEPROM) Bit Position 7 6 5 4 3 2 1 0 20 VOUT_MODE Bit Position 7 6 5 4 3 2 1 0 20 VOUT_MODE Bit Position 7 6			OPERATION	l comm	iands (b	it5 and	bit7 mu	st be 0)				
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13 STORE_DEFAULT_CODE module Bit Position 7 6 5 4 3 2 1 0 Access w w w w w w w w w 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) Restores the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Restores the value in the data byte from the value in the module non-volatile memory (EEPROM) 18 Position 7 6 5 4 3 2 1 0 20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed 10 10 10 10 20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed 10 10 10 10												
13 STORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 Access w				in the d	ata byte	e into no	on-volat	ile men	nory (EE	PROM) (on the	
Function Command code 14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 Access w w w w w w w w 20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed 20 VOUT_MODE Bit Position 7 6 5 4 3 2 1 0 Access r r r r r r r r	13	STORE_DEFAULT_CODE		7	6	5	4	3	2	1	0	
14 RESTORE_DEFAULT_CODE Restores the current register setting in the module whose command code matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 Bit Position 7 6 5 4 3 2 1 0 Access w w w w w w w w 20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed 20 VOUT_MODE Bit Position 7 6 5 4 3 2 1 0 Access r r r r r r r r				W	W					W	W	
14 RESTORE_DEFAULT_CODE matches the value in the data byte from the value in the module non-volatile memory (EEPROM) 14 RESTORE_DEFAULT_CODE Bit Position 7 6 5 4 3 2 1 0 Access w w w w w w w w w 20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed The module has MODE set to Linear and Exponent set to -10. These values cannot be changed 20 VOUT_MODE Bit Position 7 6 5 4 3 2 1 0 Access r r r r r r r r r			-									
14 RESTORE_DEFAULT_CODE memory (EEPROM) Bit Position 7 6 5 4 3 2 1 0 Access w												
Bit Position 7 6 5 4 3 2 1 0 Access w				in ule u				= 111 1119	nouule		natile	
Function Command code 20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed Bit Position 7 6 5 4 3 2 1 0 Access r r r r r r r r Function Mode Exponent	14	RESTORE_DEFAULT_CODE		7	6	5	4	3	2	1	0	
20 VOUT_MODE The module has MODE set to Linear and Exponent set to -10. These values cannot be changed Bit Position 7 6 5 4 3 2 1 0 Access r r r r r r r r Function Mode Exponent				W	W					W	w	
Bit Position 7 6 5 4 3 2 1 0 VOUT_MODE Access r <td></td> <td>]</td> <td></td>]	
Bit Position 7 6 5 4 3 2 1 0 Access r					to Lineo	ar and E	xponen	t set to	-10. The	ese valu	ies	
20 VOU1_MODE Access r r r r r r Function Mode Exponent					6	5	4	٦	2	1	0	
Function Mode Exponent	20	20 VOUT_MODE										
Default Value 0 0 1 0 1 0			Function					E	xponer	nt		
			Default Value	0	0	0	1	0	1	1	0	

Hex Code	Command			Bri	ief Desc	ription					Non-Volatile Memory Storage
		Apply a fixed offset	voltage	e to the	output	voltage	commo	and valu	ie		
		Format				vo's cor					
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	.,		.,		Byte	.,	.,	.,	
22	VOUT_TRIM	Default Value	0	0	0	0	0	0	0	0	YES
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	17 VV	1/ W	17 W			17 VV	1/ VV	17 W	
			0			1	Byte				
		Default Value	0	0	0	0	0	0	0	0	
		Sets the target volt	age for	margin	ing the	output	high				
		Format				vo's cor		ent bina	ry		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function					Byte				
25	VOUT_MARGIN_HIGH	Default Value	0	0	0	0	0	1	0	1	YES
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function					Byte				
		Default Value	0	1	0	0	0	1	1	1	
		Sets the target volt	age for	marain	ina the i	outout l	ow				
		Format	age tet			vo's cor		nt hina	rv		
		Bit Position	7	6	5	4	3	2	1	0	
	26 VOUT MARGIN LOW	Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	1	1/ W	17 W			17.00	1/ VV	17.00	
26			0	0			Byte	1	0		YES
		Default Value	0	0	0	0	0	1	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function				1	Byte				
		Default Value	0	1	0	1	0	0	0	1	
		Sets the scaling of t ratio	the outp								
		Format		L	inear, tv	<i>w</i> o's cor	npleme	ent bina	ry		
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r/w	r/w	
29	VOUT SCALE LOOP	Function			Exponer				Mantiss		YES
25	VOUL_JOALL_LOUI	Default Value	1	0	1	1	1	0	0	1	123
		Bit Position	7	6	5	4	3	2	1	0	
			r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Access	T/W	T/W	T/W			I/W	T/W	T/W	
		Function Default Value	0	0	0	Man 0	tissa 0	0	0	0	
		Sets the value of in	out volt	aae at v	which th	ne modi	ile turn	son			
		Format				NO'S COR			rv		
		Bit Position	7	6	5	4	3	2	1	0	
		Access			-						
			r	r	r	r	r	r	r Mantica	r	
35	VIN_ON	Function	1	1	Exponer		0		Mantiss		YES
_		Default Value	1	1	1	1	0	0	0	0	-
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function				Man	tissa				
		Default Value	0	0	0	0	1	0	1	1	
							·				

36	VIN_OFF IOUT_CAL_GAIN	output current Format Bit Position Access	7 r 1 7 r 0	L 6 r 1 6 r/w 0 in corre	inear, tv 5 r xponer 1 5 r/w	vo's cor 4 r nt 1 4 r/w Man 0	npleme 3 r 0 3 r/w tissa 1	nt bina 2 r 0 2 r/w 0	1 r Mantisse 0 1 r/w 1	0 r a 0 0 r/w	YES							
		Format Bit Position Access Function Default Value Bit Position Access Function Default Value Returns the value of output current Format Bit Position Access	7 r 1 7 r 0	L 6 r 1 6 r/w 0 in corre	inear, tv 5 r xponer 1 5 r/w	vo's cor 4 r nt 1 4 r/w Man 0	npleme 3 r 0 3 r/w tissa 1	nt bina 2 r 0 2 r/w 0	1 r Mantisse 0 1 r/w 1	r a 0 r/w	YES							
		Access Function Default Value Bit Position Access Function Default Value Returns the value of output current Format Bit Position Access	r 1 7 r 0 f the gc	r E 1 6 r/w 0 ain corre	r xponer 1 5 r/w	r 1 4 r/w Man 0	r 0 3 r/w tissa 1	r 0 2 r/w 0	r Mantissa 0 1 r/w	r a 0 r/w	YES							
		Function Default Value Bit Position Access Function Default Value Returns the value of output current Format Bit Position Access	1 7 r 0 f the gc	E 1 6 r/w 0	xponer 1 5 r/w 0	1 4 r/w Man 0	0 3 r/w tissa 1	0 2 r/w	Mantissa 0 1 r/w 1	a 0 0 r/w	YES							
		Default Value Bit Position Access Function Default Value Returns the value of output current Format Bit Position Access	7 r 0 f the go	1 6 r/w 0 ain corre	1 5 r/w 0	1 4 r/w Man 0	3 r/w tissa 1	0 2 r/w 0	0 1 r/w 1	0 0 r/w	YES							
		Bit Position Access Function Default Value Returns the value of output current Format Bit Position Access	7 r 0 f the go	1 6 r/w 0 ain corre	1 5 r/w 0	1 4 r/w Man 0	3 r/w tissa 1	2 r/w 0	1 r/w 1	0 r/w	YES							
38	IOUT_CAL_GAIN	Access Function Default Value Returns the value of output current Format Bit Position Access	r 0 f the go	r/w 0 ain corre	r/w 0	r/w Man 0	r/w tissa 1	r/w 0	r/w 1	r/w								
38	IOUT_CAL_GAIN	Function Default Value Returns the value of output current Format Bit Position Access	0 f the gc	0 ain corre	0	Man 0	tissa 1	0	1									
38	IOUT_CAL_GAIN	Default Value Returns the value of output current Format Bit Position Access	f the go	ain corre		0	1		_	0								
38	IOUT_CAL_GAIN	Returns the value of output current Format Bit Position Access	f the go	ain corre		0	1		_	0								
38	IOUT_CAL_GAIN	output current Format Bit Position Access	_		ection te	erm use	d to cor											
38	IOUT_CAL_GAIN	Format Bit Position Access	7	L			turns the value of the gain correction term used to correct the measured											
38	IOUT_CAL_GAIN	Bit Position Access	7	L														
38	IOUT_CAL_GAIN	Access	7				npleme	nt bina	ry									
38	IOUT_CAL_GAIN			6	5	4	3	2	1	0								
38	IOUT_CAL_GAIN		r	r	r	r	r	r	r	r/w								
		Function			xponer				Mantiss		YES							
		Default Value	1	0	0	0	1	0	0	V								
		Bit Position	7	6	5	4	3	2	1	0								
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w								
		Function				Man												
		Default Value		V: Vc	ariable k	ased or	n factor	y calibr	ation									
		Returns the value o output current	turns the value of the offset correction term used to correct the measured tput current															
		Format		L	inear, tv	vo's cor	npleme	nt bina	ry									
		Bit Position	7	6	5	4	3	2	1	0								
		Access	r	r	r	r	r	r/w	r	r								
39	IOUT_CAL_OFFSET	Function		E	Exponer	nt			Mantiss	a	YES							
		Default Value	1	1	1	0	0	V	0	0								
		Bit Position	7	6	5	4	3	2	1	0								
		Access	r	r	r/w	r/w	r/w	r/w	r/w	r/w								
		Function				Man												
		Default Value	0	0	V: Vc	ariable b	pased or	n factor	y calibro	ation								
		Sets the voltage lev Suggested value sh voltage. Values car	iown fo	r 1.2Vo.	Should	be char	nged for	differe	ent outpu									
		Format				vo's cor												
		Bit Position	7	6	5	4	3	2	1	0								
4.0		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	1150							
40	VOUT_OV_FAULT_LIMIT	Function				High	Byte			_	YES							
		Default Value	0	0	0	0	0	1	0	1								
		Bit Position	7	6	5	4	3	2	1	0								
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w								
		Function				Low	Byte											
		Default Value	0	1	1	0	0	0	0	0								
		Instructs the modu fault	le on wł	hat actio					tput ove	rvoltage								
		Format				Jnsigne	d Binary											
/11		Bit Position	7	6	5	4	3	2	1	0	YES							
41		Access	r/w RSP	r/w RSP	r/w	r/w	r/w	r	r	r								
		Function	[1]	[0]	RS[2]	RS[1]	RS[0]	Х	Х	Х								
		Default Value	1	1	1	1	1	1	0	0								

Hex Code	Command			Bri	ief Desc	ription					Non-Volatile Memory Storage
		Sets the voltage lev Suggested value sh voltage. Values can	iown for	r 1.2Vo. 6, 90%,	Should 88% or	be char 85% of	nged for output	differe voltage	nt outpi	d at -10. ut	
		Format Bit Position	7	L 6	inear, tv 5	vo's cor 4	npleme 3	nt bina 2	ry 1	0	
44	VOUT UV FAULT LIMIT	Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	YES
		Function Default Value	0	0	0	0	Byte 0	1	0	0	
		Bit Position Access	7 r/w	6 r/w	5 r/w	4 r/w	3 r/w	2 r/w	1 r/w	0 r/w	
		Function Default Value	0	0	1		Byte 1	0	0	1	
		Instructs the modul	-			⊥ ke in res	-	-		T	
		undervoltage fault Format					d Binar				
45	45 VOUT_UV_FAULT_RESPONSE	Bit Position	7	6	5	4	3	2	1	0	YES
-13		Access	r/w RSP	r/w RSP	r/w	r/w	r/w	r	r	r	125
		Function Default Value	[1] 0	[0] 0	RS[2]	RS[1]	RS[0]	X 1	X 0	X 0	
		Sets the output ove	-	~	÷				0	0	
		Format		L	inear, tv	vo's cor	npleme		<u> </u>		
	46 IOUT OC FAULT LIMIT	Bit Position Access	7 r	6 r	5 r	4 r	3 r	2 r	1 r	0 r	
46		Function			xponer				Mantiss		YES
10		Default Value Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	R	
		Function Default Value	0	0	1	Man 1	tissa 0	1	0	0	
		Sets the output ove	ercurren	t warni	ng level	in A					
		Format Bit Position	7	L 6	inear, tv 5	vo's cor 4	npleme 3	nt bina 2	ry 1	0	
		Access	r	r	r	r r	r	r	r	r	
4A	IOUT OC WARN LIMIT	Function Default Value	1		Exponer		1		Mantiss		YES
		Bit Position	1 7	1 6	1 5	1 4	1 3	0	0	0	
		Access Function	r	r	r/w	r/w	r/w tissa	r/w	r/w	r/w	
		Default Value	0	0	1	1	0	0	1	0	
		Sets the output volt	tage lev								
		Format Bit Position	7	6	inear, tv 5	vo's cor 4	npleme 3	nt bina 2	ry 1	0	
	5E POWER_GOOD_ON	Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
5E		Function Default Value	0	0	0	High 0	Byte 0	1	0	0	YES
		Bit Position	7	6	5	4	3	2	1	0	
		Access Function	r/w	r/w	r/w	r/w Low	r/w Byte	r/w	r/w	r/w	
		Default Value	0	1	1	0	1	0	1	0	

		Brief Description						Non-Volatile Memory Storage			
1 1		Sets the output volt Format	tage lev		nich the inear, tu						
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
5F	POWER GOOD OFF	Function		_		<u> </u>	Byte		0		YES
		Default Value Bit Position	0	0	0	0	0	1	0	0	
		Access	r/w	r/w	c/w	r/w	r/w	r/w	r/w	r/w	
		Function	17 00	17 VV	17 00		Byte	17 00	17 VV	17 VV	
		Default Value	0	1	0	1	0	0	1	0	
		Sets the rise time of	f the our	tout vol	taao du	rina cto	irtun				
		Format			inear, tu			nt hinar	W.		
		Bit Position	7	6	5	4	3	2	y 1	0	
		Access	r	r	r	r	r	r	r	r/w	
61	TON RISE	Function		E	xponer	it		1	1antiss	a	YES
01	TON_RISE	Default Value	1	1	1	0	0	0	0	0	YES
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r/w	r/w	r/w	r/w	r/w	r/w	r/w	r/w	
		Function	0	0	1		tissa 1	0	1	1	
		Default Value	0	0		0	1	0	1	1	
		Returns one byte of faults	finform	ation w		-			ical mo	dule	
		Format	_				d Binar				
78 STATUS_BYTE	Bit Position	7	6	5	4	3	2	1	0		
		Access	r	r	r VOUT	n TUOL	r VIN II	r	r	r OTHE	
		Flag	Х	OFF	OV	IOUT_ OC	VIN_U V	TEMP	CML	R	
		Default Value	0	0	0	0	0	0	0	0	
		Returns two bytes of conditions								warning	
		Format			ι	Jnsigne	ed binar	У			
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r	r	r	r	r	r	
79	STATUS_WORD	Flag	VOUT	IOUT_ OC	Х	Х	PGOO D	Х	Х	Х	
		Default Value	0	0	0	0	0	0	0	0	
		Bit Position	7	6	5	4	3	2	1	0	
		Access	r	r	r VOUT	r IOUT	r VIN_U	r	r	r OTHE	
		Flag Dofault Value		OFF	_OV	00	V	TEMP	CML	R	
		Default Value	0	0	0	0	0	0	0	0	
		Returns one byte of related faults	f inform	ation w					output v	voltage	
		Format				Jnsigne	ed Binar				
7A	STATUS_VOUT	Bit Position	7	·	6 5		4		2 1	0	
		Access	r		r r		r		r r	r	
		Flag Default Value	VOUT 0		X X 0 0		JT_UV 0		X X 0 0	X 0	
		Returns one byte of related faults	f inform	ation w					output c	current	
		Format			l	Jnsigne	d Binar				
7B	STATUS_IOUT	Bit Position	7		6	5		4 3	2	1 0	
		Access	r		r	r		r r		r r	
		Flag Default Value	IOUT_ 0		X 10	UT_OC_ 0	_WARN	X X 0 0		X X 0 0	

Hex Code	Command			E	Brief Des	criptio	on					Non-Volatile Memory Storage
		Returns one byte o related faults	f inform	ation	with the	status	ofth	e mo	dule's	temper	ature	
		Format			Unsigned Binary							
7D	STATUS_TEMPERATURE	Bit Position	7		6		5	4	3		1 0	
		Access	r		r		r	r	r		r r	
		Flag	OT_F/		OT_W		X	Х	X		XX	
		Default Value	0		C)	0	0	0	0	0 0	
		Returns one byte o related faults	f inform	ation	with the					commu	unication	
		Format			-	Unsig				-		
75		Bit Position	7		6	5	4	3	2	1	0	
7E	STATUS_CML	Access	r		r	r	r	r	r	r Other	r	
		Flag	Inva Comm	-	Invalid Data	PEC Fail	х	Х	х	Othe Comr Fault	n X	
		Default Value	0		0	0	0	0	0	0	0	
		Returns the value of	of the inp	out vo								
		Format			Linear,							
		Bit Position	7	6	5	4		3	2	1	0	
		Access	r	r	r	r		r	r	r	r	
88	READ_VIN	Function			Expone	-				Mantiss		
00		Default Value	1	1	0	1		1	0	0	0	
		Bit Position	7	6	5	4		3	2	1	0	
		Access	r	r	r	r		r ~	r	r	r	
		Function Default Value	0	0	0	0	antiss	a 0	0	0	0	
		–				-		-	0	0	0	
		Returns the value of	of the ou	itput v	voltage c	of the r	nodul	е				
		Format			Linear,							
		Bit Position	7	6	5	4		3	2	1	0	
		Access Function	r	r	r	r	antiss	r	r	r	r	
8B	READ_VOUT	Default Value	0	0	0	0		0	0	0	0	
		Bit Position	7	6	5	4		3	2	1	0	
		Access	r	r	r	r		r	r	r	r	
		Function					antiss					
		Default Value	0	0	0	0		0	0	0	0	
		Returns the value c	of the ou	itout c	urrent o	of the n	noduli	<u></u>				
		Format		pur (Linear, 1				nt bind	ary		
		Bit Position	7	6	5	4		3	2	1	0	
		Access	r	r	r	r		r	r	r	r	
8C	READ_IOUT	Function			Expone	nt				Mantiss	50	
	REAU_IUUT	Default Value	1	1	1	0		0	0	0	0	
		Bit Position	7	6	5	4		3	2	1	0	
		Access	r	r	r	r		r	r	r	r	
		Function	0	0		-	antiss	-	0	<u> </u>		
		Default Value	0	0	0	0		0	0	0	0	
		Returns one byte in only)	ndicating	g the r	module i					Spec. 1.1	L (read	
98	PMBUS_REVISION	Format Bit Desition	~	<i>с</i>		Unsig				1		YES
-		Bit Position	7 r	6 r	5	4		3 r	2	1	0	
		Access Default Value	r O	r 0	r O	r 1		r O	r O	r O	r 1	
			U	U	U	1		U	U	U		

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Hex Non-Volatile Command **Brief Description** Code Memory Storage Returns the minimum input voltage the module is specified to operate at (read only) Format Linear, two's complement binary **Bit Position** 7 6 5 4 3 2 1 0 Access r r r r r r Function Exponent Mantissa MFR VIN MIN YES A0 **Default Value** 1 1 0 0 0 0 **Bit Position** 7 6 5 4 0 3 2 1 Access r r r r r r r r Function Mantissa **Default Value** 0 0 0 0 1 0 0 1 Returns the minimum output voltage possible from the module (read only) Format Linear, two's complement binary **Bit Position** 7 0 6 5 4 3 Access r r r r r r r r Function Exponent Mantissa A4 MFR_VOUT_MIN YES **Default Value** 0 0 0 0 0 0 0 1 **Bit Position** 7 6 5 4 3 2 0 Access r r r r r r r r Function Mantissa Default Value 0 0 1 0 1 1 0 1 Returns module name information (read only) Unsigned Binary Format **Bit Position** 6 5 4 0 3 2 Access r r r r r r Function Reserved YES D0 MFR_SPECIFIC_00 **Default Value** 0 0 0 0 0 0 0 0 **Bit Position** 7 6 5 4 3 2 1 0 Access r r r r r r r Function Module Name Reserved Default Value 0 0 0 0 0 1 0 Applies an offset to the READ_VOUT command results to calibrate out offset errors in module measurements of the output voltage (between -125mV and +124mV) Format Linear, two's complement binary **Bit Position** 4 0 6 5 3 2 Access r/w r r r r r r r D4 VOUT_CAL_OFFSET Function Mantissa YES Default Value V 0 0 0 0 0 0 0 **Bit Position** 5 0 7 6 4 3 2 1 Access r r/w r/w r/w r/w r/w r/w r/w Function Mantissa Default Value V V V V V V V V Applies a gain correction to the READ_VOUT command results to calibrate out gain errors in module measurements of the output voltage (between -0.125 and 0.121) Format Linear, two's complement binary **Bit Position** 7 5 4 3 0 6 2 1 Access r r/w r r r r r r D5 Function Exponent Mantissa YES VOUT_CAL_GAIN Default Value 1 0 0 0 0 0 V 1 7 **Bit Position** 6 3 2 0 5 4 1 Access r/w r/w r/w r/w r/w r r r Mantissa Function **Default Value** V V V V V V V V

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Hex Non-Volatile Command **Brief Description** Code Memory Storage Applies an offset correction to the READ_VIN command results to calibrate out offset errors in module measurements of the input voltage (between -2V and +1.968V) Format Linear, two's complement binary **Bit Position** 6 5 4 3 0 7 2 Access r r r r r r r/w r D6 VIN_CAL_OFFSET Function Exponent Mantissa YES Default Value 0 V 0 V 1 1 1 0 **Bit Position** 7 6 5 4 3 2 1 0 r/w Access r r r/w r/w r/w r/w r/w Function Mantissa V V **Default Value** 0 0 V V V V Applies a gain correction to the READ_VIN command results to calibrate out gain errors in module measurements of the input voltage (between -0.125 and 0.121) Linear, two's complement binary Format **Bit Position** 7 6 5 4 3 1 0 Access r r r r r/w r r r Exponent D7 Function Mantissa YES VIN_CAL_GAIN **Default Value** V V 1 1 0 0 0 0 7 5 3 2 0 **Bit Position** 6 4 1 Access r r r r/w r/w r/w r/w r/w Function Mantissa **Default Value** 0 0 0 V V V V V

Thermal Considerations

GF

Power modules operate in a variety of thermal environments; however, sufficient cooling should always be provided to help ensure reliable operation.

Considerations include ambient temperature, airflow, module power dissipation, and the need for increased reliability. A reduction in the operating temperature of the module will result in an increase in reliability. The thermal data presented here is based on physical measurements taken in a wind tunnel. The test set-up is shown in Figure 48. The preferred airflow direction for the module is in Figure 49.

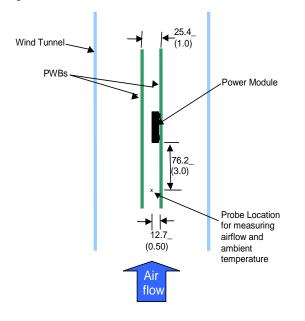


Figure 48. Thermal Test Setup.

The thermal reference points, T_{ref} used in the specifications are also shown in Figure 49. For reliable operation the temperatures at these points should not exceed 120°C. The output power of the module should not exceed the rated power of the module (Vo,set x Io,max).

Please refer to the Application Note "Thermal Characterization Process For Open-Frame Board-Mounted Power Modules" for a detailed discussion of thermal aspects including maximum device temperatures.

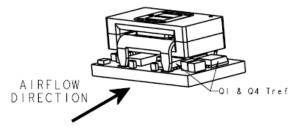


Figure 49. Preferred airflow direction and location of hotspot of the module (Tref).

3Vdc –14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Shock and Vibration

The ruggedized (-D version) of the modules are designed to withstand elevated levels of shock and vibration to be able to operate in harsh environments. The ruggedized modules have been successfully tested to the following conditions:

Non operating random vibration:

Random vibration tests conducted at 25C, 10 to 2000Hz, for 30 minutes each level, starting from 30Grms (Z axis) and up to 50Grms (Z axis). The units were then subjected to two more tests of 50Grms at 30 minutes each for a total of 90 minutes.

Operating shock to 40G per Mil Std. 810G, Method 516.4 Procedure I:

The modules were tested in opposing directions along each of three orthogonal axes, with waveform and amplitude of the shock impulse characteristics as follows:

All shocks were half sine pulses, 11 milliseconds (ms) in duration in all 3 axes.

Units were tested to the Functional Shock Test of MIL-STD-810, Method 516.4, Procedure I - Figure 516.4-4. A shock magnitude of 40G was utilized. The operational units were subjected to three shocks in each direction along three axes for a total of eighteen shocks.

Operating vibration per Mil Std 810G, Method 514.5 Procedure I:

The ruggedized (-D version) modules are designed and tested to vibration levels as outlined in MIL-STD-810G, Method 514.5, and Procedure 1, using the Power Spectral Density (PSD) profiles as shown in Table 7 and Table 8 for all axes. Full compliance with performance specifications was required during the performance test. No damage was allowed to the module and full compliance to performance specifications was required when the endurance environment was removed. The module was tested per MIL-STD-810, Method 514.5, Procedure I, for functional (performance) and endurance random vibration using the performance and endurance levels shown in Table 7 and Table 8 for all axes. The performance test has been split, with one half accomplished before the endurance test and one half after the endurance test (in each axis). The duration of the performance test was at least 16 minutes total per axis and at least 120 minutes total per axis for the endurance test. The endurance test period was 2 hours minimum per axis.

Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)
10	1.14E-03	170	2.54E-03	690	1.03E-03
30	5.96E-03	230	3.70E-03	800	7.29E-03
40	9.53E-04	290	7.99E-04	890	1.00E-03
50	2.08E-03	340	1.12E-02	1070	2.67E-03
90	2.08E-03	370	1.12E-02	1240	1.08E-03
110	7.05E-04	430	8.84E-04	1550	2.54E-03
130	5.00E-03	490	1.54E-03	1780	2.88E-03
140	8.20E-04	560	5.62E-04	2000	5.62E-04

Table 7: Performance Vibration Qualification - All Axes

Table 8: Endurance Vibration Qualification - All Axes

1 million 1					
Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)	Frequency (Hz)	PSD Level (G2/Hz)
10	0.00803	170	0.01795	690	0.00727
30	0.04216	230	0.02616	800	0.05155
40	0.00674	290	0.00565	890	0.00709
50	0.01468	340	0.07901	1070	0.01887
90	0.01468	370	0.07901	1240	0.00764
110	0.00498	430	0.00625	1550	0.01795
130	0.03536	490	0.01086	1780	0.02035
140	0.0058	560	0.00398	2000	0.00398

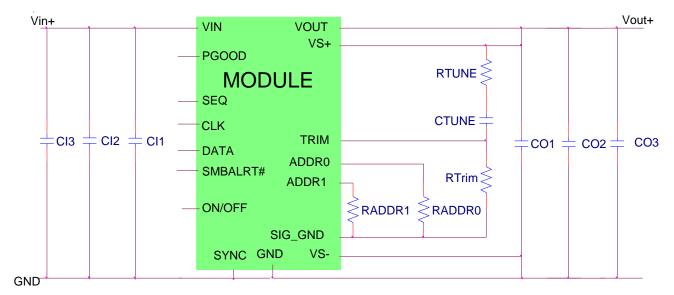
20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Example Application Circuit

Requirements:

Vin:	12V
Vout:	1.8V
lout:	15A max., worst case load transient is from 10A to 15A
∆Vout:	1.5% of Vout (27mV) for worst case load transient
Vin, ripple	1.5% of Vin (180mV, p-p)



CI1	Decoupling cap - 1x0.047 μ F/16V ceramic capacitor (e.g. Murata LLL185R71C473MA01)
CI2	3x22µF/16V ceramic capacitor (e.g. Murata GRM32ER61C226KE20)
CI3	470μF/16V bulk electrolytic
CO1	Decoupling cap - 1x0.047 μ F/16V ceramic capacitor (e.g. Murata LLL185R71C473MA01)
CO2	N.A.
CO3	3 × 330μF/6.3V Polymer (e.g. Sanyo Poscap)
CTune	4700pF ceramic capacitor (can be 1206, 0805 or 0603 size)
RTune	330 ohms SMT resistor (can be 1206, 0805 or 0603 size)
RTrim	$10 \text{k}\Omega$ SMT resistor (can be 1206, 0805 or 0603 size, recommended tolerance of 0.1%)

<u>Note:</u> The DATA, CLK and SMBALRT pins do not have any pull-up resistors inside the module. Typically, the SMBus master controller will have the pull-up resistors as well as provide the driving source for these signals.

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

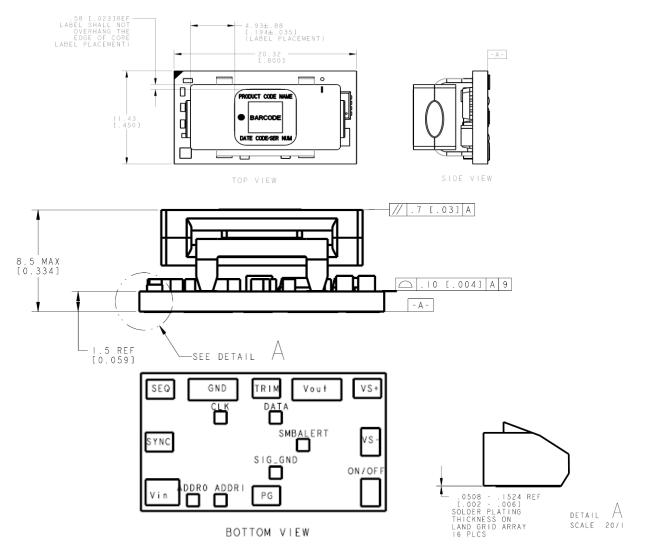
Mechanical Outline

GE

Dimensions are in millimeters and (inches).

Tolerances: x.x mm \pm 0.5 mm (x.xx in. \pm 0.02 in.) [unless otherwise indicated]

x.xx mm \pm 0.25 mm (x.xxx in \pm 0.010 in.)



PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	10	SYNC ¹
2	VIN	11	CLK
3	SEQ	12	DATA
4	GND	13	SMBALERT#
5	TRIM	14	SIG_GND
6	VOUT	15	ADDR1
7	VS+	16	ADDR0
8	VS-		
9	PG		

¹ If unused, connect to Ground.

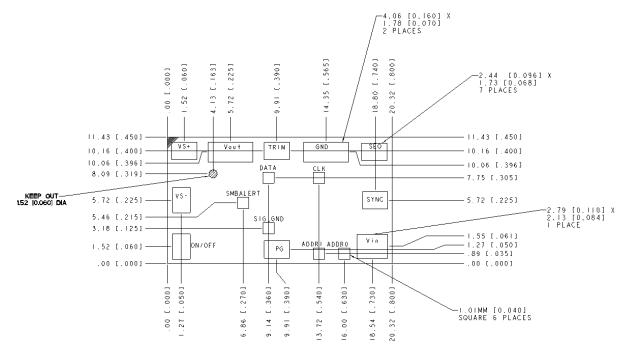
3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Recommended Pad Layout

Dimensions are in millimeters and (inches).

Tolerances: x.x mm \pm 0.5 mm (x.xx in. \pm 0.02 in.) [unless otherwise indicated]

x.xx mm \pm 0.25 mm (x.xxx in \pm 0.010 in.)



RECOMMENDED FOOTPRINT -THROUGH THE BOARD-

PIN	FUNCTION	PIN	FUNCTION
1	ON/OFF	10	SYNC ²
2	VIN	11	CLK
3	SEQ	12	DATA
4	GND	13	SMBALERT#
5	TRIM	14	SIG_GND
6	VOUT	15	ADDR1
7	VS+	16	ADDR0
8	VS-		
9	PG		

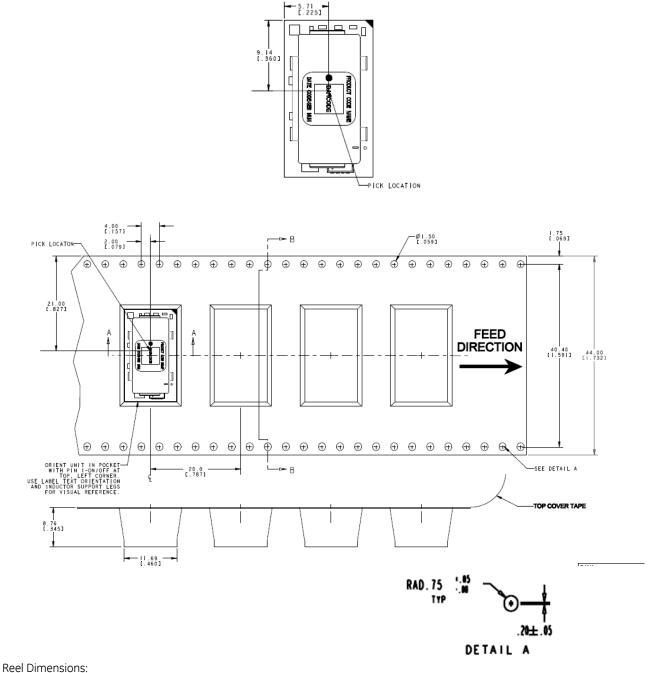
² If unused, connect to Ground.

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Packaging Details

The 12V Digital MicroDLynx[™] 20A modules are supplied in tape & reel as standard. Modules are shipped in quantities of 200 modules per reel.

All Dimensions are in millimeters and (in inches).



Outside Dimensions: Inside Dimensions: Tape Width:

330.2 mm (13.00) 177.8 mm (7.00") 44.00 mm (1.732")

Surface Mount Information

Pick and Place

GF

The 20A Digital MicroDLynx[™] modules use an open frame construction and are designed for a fully automated assembly process. The modules are fitted with a label designed to provide a large surface area for pick and place operations. The label meets all the requirements for surface mount processing, as well as safety standards, and is able to withstand reflow temperatures of up to 300°C. The label also carries product information such as product code, serial number and the location of manufacture.

Nozzle Recommendations

The module weight has been kept to a minimum by using open frame construction. Variables such as nozzle size, tip style, vacuum pressure and placement speed should be considered to optimize this process. The minimum recommended inside nozzle diameter for reliable operation is 3mm. The maximum nozzle outer diameter, which will safely fit within the allowable component spacing, is 7 mm.

Bottom Side / First Side Assembly

Only the -D version of this module can be placed at the bottom side of the customer board. No additional glue or adhesive is required to hold the module during the top side reflow process. Serial numbers with date codes starting from 19xx21xxxxxx (19 – year, 21 – week) are suitable for bottom side placement.

Lead Free Soldering

The modules are lead-free (Pb-free) and RoHS compliant and fully compatible in a Pb-free soldering process. Failure to observe the instructions below may result in the failure of or cause damage to the modules and can adversely affect long-term reliability.

Pb-free Reflow Profile

Power Systems will comply with J-STD-020 Rev. C (Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices) for both Pb-free solder profiles and MSL classification procedures. This standard provides a recommended forced-air-convection reflow profile based on the volume and thickness of the package (table 4-2). The suggested Pb-free solder paste is Sn/Ag/Cu (SAC). For questions regarding Land grid array(LGA) soldering, solder volume; please contact GE for special manufacturing process instructions. The recommended linear reflow profile using Sn/Ag/Cu solder is shown in Fig. 50. Soldering outside of the recommended profile requires testing to verify results and performance.

MSL Rating

The 20A Digital MicroDLynx^TM modules have a MSL rating of 2a.

Storage and Handling

The recommended storage environment and handling procedures for moisture-sensitive surface mount packages

is detailed in J-STD-033 Rev. A (Handling, Packing, Shipping and Use of Moisture/Reflow Sensitive Surface Mount Devices). Moisture barrier bags (MBB) with desiccant are required for MSL ratings of 2 or greater. These sealed packages should not be broken until time of use. Once the original package is broken, the floor life of the product at conditions of \leq 30°C and 60% relative humidity varies according to the MSL rating (see J-STD-033A). The shelf life for dry packed SMT packages will be a minimum of 12 months from the bag seal date, when stored at the following conditions: $< 40^{\circ}$ C, < 90% relative humidity.

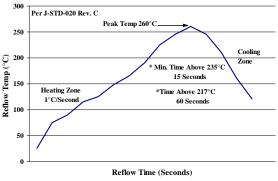


Figure 50. Recommended linear reflow profile using Sn/Ag/Cu solder.

Post Solder Cleaning and Drying Considerations

Post solder cleaning is usually the final circuit-board assembly process prior to electrical board testing. The result of inadequate cleaning and drying can affect both the reliability of a power module and the testability of the finished circuit-board assembly. For guidance on appropriate soldering, cleaning and drying procedures, refer to *Board Mounted Power Modules: Soldering and Cleaning* Application Note (AN04-001).

GF

20A Digital MicroDLynxTM: Non-Isolated DC-DC Power Modules

3Vdc -14.4Vdc input; 0.45Vdc to 5.5Vdc output; 20A Output Current

Ordering Information

Please contact your GE Sales Representative for pricing, availability and optional features.

Table 9. Device Codes

Device Code Input Voltage Range		Output Voltage			Sequencing	Comcodes
UDT020A0X3-SRZ	3 – 14.4Vdc	0.45 – 5.5Vdc	20A	Negative	Yes	CC109159728
UDT020A0X3-SRDZ	3 – 14.4Vdc	0.45 – 5.5Vdc	20A	Negative	Yes	CC109168745
UDT020A0X43-SRZ	3 – 14.4Vdc	0.45 – 5.5Vdc	20A	Positive	Yes	CC109159736

-Z refers to RoHS compliant parts

Table 10. Coding Scheme

Package Identifier	Family	Sequencing Option	Output current	Output voltage	On/Off logic	Remote Sense	Options		ROHS Compliance
U	D	Т	020A0	х		3	-SR	-D	Z
P=Pico U=Micro M=Mega G=Giga	D=Dlynx Digital V = DLynx Analog.	T=with EZ Sequence X=without sequencing	20A	X = progra mmable output	4 = positive No entry = negative	3 = Remote Sense	S = Surface Mount R = Tape & Reel	D = 105°C operating ambient, 40G operating shock as per MIL Std. 810G,	Z = ROHS6

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W004062061 A1, W004062062A1, W004070780A3, W004084390A3, W004084391A3, W005079227A3, W005081771A3, W006019569A3, W02007001584A3, W02007094935A3

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Как с нами связаться

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